

Ultra-Low Voltage R to F Flash MCU

BH67F2132

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Features

CPU Features

- Operating Voltage: 1.1V ~ 2.2V
- Up to 31µs instruction cycle with 128kHz system clock
- Power down and wake-up functions to reduce power consumption
- Multi-mode operation: NORMAL, IDLE and SLEEP
- Fully integrated 32/64/128kHz oscillator requires no external components
- · All instructions executed in one or two instruction cycles
- · Table read instructions
- 63 powerful instructions
- · 4-level subroutine nesting
- · Bit manipulation instruction

Peripheral Features

- Flash Program Memory: 2K×16
- RAM Data Memory: 128×8
- True EEPROM Memory: 128×8
- · Watchdog Timer function
- 23 bidirectional I/O lines
- One EL carrier output
- · R to F converter
- Two pin-shared external interrupts
- One Timer Module for time measure, compare match output or PWM output function
- Dual Time-Base functions for generation of fixed time interrupt signals
- LCD driver function:
 - SEGs×COMs: 22×2 or 21×3
 - Duty type: 1/2 duty or 1/3 duty
 - Bias level: 1/2 bias
 - Bias type: C type
 - Waveform type: type A or type B
- · Low voltage detect function
- Flash program memory can be re-programmed up to 100,000 times
- Flash program memory data retention > 10 years
- True EEPROM data memory can be re-programmed up to 1,000,000 times
- True EEPROM data memory data retention > 10 years
- 48-pin LQFP package type

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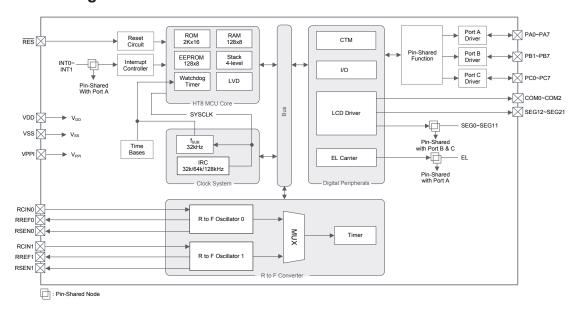
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General Description

The BH67F2132 is a Flash Memory type 8-bit high performance RISC architecture microcontroller specially designed for very low voltage especially one battery applications. Offering users the convenience of Flash Memory multi-programming features, this device also includes a wide range of functions and features. Other memory includes an area of RAM Data Memory as well as an area of true EEPROM memory for storage of non-volatile data such as serial numbers, calibration data etc.

The advantages of low operating voltage, low power consumption, I/O flexibility, timer functions, oscillator options, R to F converter, LCD driver, Power down and wake-up functions, watchdog timer, as well as low cost feature, enhance the versatility of this device to suit for the one battery applications.

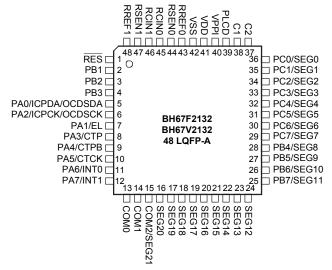
Block Diagram



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Pin Assignment



Note: 1. If the pin-shared pin functions have multiple output functions, the desired pin-shared function is determined using corresponding pin-shared software control bits.

2. The real MCU and its equivalent OCDS EV device share the same package type, however the OCDS EV device part number is BH67V2132. Pins OCDSCK and OCDSDA which are pin-shared with PA2 and PA0 are only used for the OCDS EV device.

Pin Descriptions

The function of each pin is listed in the following table, however the details behind how each pin is configured is contain in other sections of the datasheet.

Pin Name	Function	OPT	I/T	O/T	Description
DA O // ODD A /	PA0	PAPU PAWU	ST	CMOS	General purpose I/O. Register enabled pull-up and wake-up.
PA0/ICPDA/ OCDSDA	ICPDA	_	ST	CMOS	In-circuit programming data/address pin
CODODA	OCDSDA	_	ST	CMOS	On-chip debug support data/address pin, for EV chip only
PA1/EL	PA1	PAPU PAWU PAS0	ST	CMOS	General purpose I/O. Register enabled pull-up and wake-up.
	EL	PAS0	_	CMOS	EL carrier output
DA O/IODOI//	PA2	PAPU PAWU	ST	CMOS	General purpose I/O. Register enabled pull-up and wake-up.
PA2/ICPCK/ OCDSCK	ICPCK	_	ST	_	In-circuit programming clock pin
COBCOR	OCDSCK	_	ST	_	On-chip debug support clock pin, for EV chip only
PA3/CTP	PA3	PAPU PAWU PAS0	ST	CMOS	General purpose I/O. Register enabled pull-up and wake-up.
	CTP	PAS0	_	CMOS	CTM output
PA4/CTPB	PA4	PAPU PAWU PAS1	ST	CMOS	General purpose I/O. Register enabled pull-up and wake-up.
	СТРВ	PAS1	_	CMOS	CTM inverted output

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Pin Name	Function	ОРТ	I/T	O/T	Description
PA5/CTCK	PA5	PAPU PAWU	ST	CMOS	General purpose I/O. Register enabled pull-up and wake-up.
	CTCK	CTMC0	ST	_	CTM clock input
PA6/INT0	PA6	PAPU PAWU	ST	CMOS	General purpose I/O. Register enabled pull-up and wake-up.
	INT0	INTEG	ST	_	External interrupt 0
PA7/INT1	PA7	PAPU PAWU	ST	CMOS	General purpose I/O. Register enabled pull-up and wake-up.
	INT1	INTEG	ST	_	External interrupt 1
RES	RES	_	ST	_	External reset pin
PB1~PB3	PB1~PB3	PBPU	ST	CMOS	General purpose I/O. Register enabled pull-up
PB4/SEG8~PB7/ SEG11	PB4~PB7	PBPU PBS1	ST	CMOS	General purpose I/O. Register enabled pull-up
SEGII	SEG8~SEG11	PBS1	_	AN	LCD Segment output
PC0/SEG0~PC7/	PC0~PC7	PCPU PCS0 PCS1	ST	CMOS	General purpose I/O. Register enabled pull-up
SEG7	SEG0~SEG7	PCS0 PCS1	_	AN	LCD Segment output
SEG12~SEG20	SEG12~SEG20	1	_	AN	LCD Segment output
COM2/SEG21	COM2	-	_	AN	LCD Common output
CONIZ/SEGZ I	SEG21	_	_	AN	LCD Segment output
COM0~COM1	COM0~COM1	_	_	AN	LCD Common output
C1	C1	_	AN	_	LCD voltage pump
C2	C2	_	AN	_	LCD voltage pump
PLCD	PLCD	_	PWR	AN	LCD power supply
RREF0	RREF0	_	_	AN	R to F oscillator 0 output pin for reference resistor oscillation.
RSEN0	RSEN0	_	_	AN	R to F oscillator 0 output pin for sensor resistor oscillation.
RCIN0	RCIN0	_	AN	_	R to F oscillator 0 input pin for RC oscillation.
RREF1	RREF1	_	_	AN	R to F oscillator 1 output pin for reference resistor oscillation.
RSEN1	RSEN1	_	_	AN	R to F oscillator 1 output pin for sensor resistor oscillation.
RCIN1	RCIN1	_	AN	_	R to F oscillator 1 input pin for RC oscillation.
VDD	VDD	_	PWR	_	Positive power supply
VSS	VSS	_	PWR	_	Negative power supply, ground
VPPI	VPPI	_	PWR	_	Programming positive power supply

Legend: I/T: Input type; O/T: Output type

OPT: Optional by register option

PWR: Power; ST: Schmitt Trigger input CMOS: CMOS output; AN: Analog signal

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Absolute Maximum Ratings

Supply Voltage	V _{SS} -0.3V to 2.5V
Input Voltage	
Storage Temperature	50°C to 125°C
Operating Temperature	10°C to 50°C
I _{OL} Total	80mA
I _{OH} Total	80mA
Total Power Dissipation	500mW

Note: These are stress ratings only. Stresses exceeding the range specified under "Absolute Maximum Ratings" may cause substantial damage to the device. Functional operation of this device at other conditions beyond those listed in the specification is not implied and prolonged exposure to extreme conditions may affect device reliability.

D.C. Characteristics

Ta = 25°C

Complete	ol Parameter		Test Conditions	Min.	Trees	N/	Unit	
Symbol	Parameter	V _{DD}	Conditions	iviin.	Тур.	Max.	Unit	
			f _{SYS} = 32kHz	1.1	_	2.2		
V _{DD}	Operating Voltage – IRC	_	f _{SYS} = 64kHz	1.1	_	2.2	V	
			f _{SYS} = 128kHz	1.1	_	2.2		
			f _{SYS} = 32kHz	_	_	5		
I _{DD}	Normal Mode – IRC	1.5V	f _{SYS} = 64kHz	_	_	10	μΑ	
			f _{SYS} = 128kHz	_	_	20		
	SLEEP Mode	1 5\/	No load, all peripherals off, WDT off	_	0.1	1		
	SLEEF WIOGE	1.5V	No load, all peripherals off, WDT on	_	2.4	2.9	μA	
I _{STB}	IDLE Mode – IRC	1.5V	No load, all peripherals off, f _{SUB} on, f _{SYS} = 32kHz	_	_	3		
			No load, all peripherals off, f _{SUB} on, f _{SYS} = 64kHz	_	_	6	μΑ	
			No load, all peripherals off, f _{SUB} on, f _{SYS} = 128kHz	_	_	12		
V	Input Low Voltage for I/O Ports			0	_	0.2V _{DD}	V	
VIL	Input Low Voltage for RES Pin	_	_	0	_	0.4V _{DD}	V	
V	Input High Voltage for I/O Ports			0.8V _{DD}	_	V _{DD}	V	
V _{IH}	Input High Voltage for RES Pin	_	_	0.9V _{DD}	_	V _{DD}	V	
V _{DR}	RAM Data Retention Voltage	_	_	1.0	_	_	V	
I _{OL}	Sink Current for I/O Pins	1.5V	$V_{OL} = 0.1 V_{DD}$	5	10	_	mA	
Іон	Source Current for I/O Pins	1.5V	$V_{OH} = 0.9V_{DD}$	-0.9	-1.8	_	mA	
R _{PH}	Pull-high Resistance for I/O Ports	1.5V	LVPU = 0	100	200	400	kΩ	
I TYPH	Full-High Resistance for I/O Ports	1.5V	LVPU = 1	25	50	100	kΩ	
I _{LEAK}	Input Leakage Current	1.5V	$V_{IN} = V_{DD}$ or $V_{IN} = V_{SS}$	_	_	±1	μΑ	



A.C. Characteristics

 $Ta = 25^{\circ}C$

Symbol	Parameter		Test Conditions	Min.	Turn	Max.	Unit
Symbol	Parameter	V _{DD}	Conditions	WIII.	Тур.	wax.	Unit
	32kHz Trimmed IRC Frequency			-10%	32	+10%	kHz
firc	64kHz Trimmed IRC Frequency	1.5V	_	-10%	64	+10%	kHz
	128kHz Trimmed IRC Frequency			-10%	128	+10%	kHz
tstart	IRC Start-up Time	_	_	_	_	500	μs
t _{TCK}	CTCK Input Pin Minimum Pulse Width	_	_	0.4	_	_	μs
t _{INT}	External Interrupt Minimum Pulse Width	_	_	15	_	_	μs
t _{RES}	External Reset Minimum Low Pulse Width	_	_	10	_	_	μs
	System Start-up Time Wake-up from Conditions where f _{SYS} is off	_	$f_{SYS} = f_H \sim f_H/64$, $f_H = f_{IRC}$	_	16	_	t _{IRC}
t _{sst}	System Start-up Time Wake-up from Conditions where f _{SYS} is on	_	$f_{SYS} = f_H \sim f_H/64$, $f_H = f_{IRC}$	_	2	_	t _H
	System Reset Delay Time (Power-on Reset)	_	RR _{POR} = 5V/ms	36	48	60	
t _{RSTD}	System Reset Delay Time (WDTC/RSTC Register Software Reset)	_	_	30	48	60	ms
	System Reset Delay Time(WDT Overflow Reset or RES pin Reset)	_	_	12	16	20	ms
t _{DEW}	Data EEPROM Write Time	_	_	_	8	12	ms
t _{SRESET}	Minimum Software Reset Width to Reset	_	_	45	90	120	μs

LVD Electrical Characteristics

Ta = 25°C

Symbol	Parameter	1	est Conditions	Min.	Typ.	Max.	Unit
Syllibol	Farameter	V _{DD}	Conditions	IVIIII.	Typ.	IVIAX.	Ullit
V _{LVD}	Low Voltage Detector Voltage	_	LVD enable	1.10	1.15	1.20	V
t _{LVDS}	LVDO Stable Time	_	LVD off \rightarrow on	_	_	150	μs
t _{LVD}	LVD Minimum Low Voltage Width to Interrupt	_	_	60	120	240	μs
I _{LVD}	Additional Current for LVD Enable	1.5V	LVD enable	_	50	100	μΑ

R to F Converter Electrical Characteristics

Ta = 25°C

Symbol Param	Doromotor	Test Conditions			n. Tvp.	Max.	Unit
	Faranietei	V _{DD}	Conditions	Min.	тур.	Wax.	Ullit
f _{LIRC2}	LIRC2 Oscillator Clock	1.5V	_	102.4	128.0	153.6	kHz
tonlirc	LIRC2 Oscillator Stable Time	1.5V	_	_	_	1	ms
f _{AD}	RC Oscillation Frequency	1.5V	_	_	_	50	kHz

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LCD Electrical Characteristics

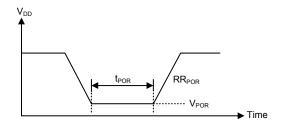
Ta = 25°C

Symbol Dovernotor			Test Conditions	Min.	Tress	Max.	Unit
Symbol	Parameter	V _{DD}	V _{DD} Conditions		Тур.	wax.	Unit
V _{IN}	LCD Operating Voltage	_	Power Supply from VDD	1.1	_	2.2	V
I _{LCD}	Additional Current for LCD Enable	1.5V	No load, VA = 2×V _{DD} , 1/2 Bias	_	1.5	3	μΑ
I _{LCDOL}	LCD Common and Segment Sink Current	1.5V	V _{OL} = 0.1V _{DD}	50	100	_	μΑ
Істон	LCD Common and Segment Source Current	1.5V	V _{OH} = 0.9V _{DD}	-50	-100	_	μΑ

Power on Reset Electrical Characteristics

Ta = 25°C

Symbol	Parameter	Т	est Conditions	Min.	Тур.	Max.	Unit
		V _{DD}	Conditions				Unit
V _{POR}	V _{DD} Start Voltage to Ensure Power-on Reset	_	_	_	_	100	mV
RR _{POR}	V _{DD} Rising Rate to Ensure Power-on Reset	_	_	0.035	_	_	V/ms
t _{POR}	Minimum Time for V _{DD} Stays at V _{POR} to Ensure Power-on Reset	_	_	1	_	_	ms



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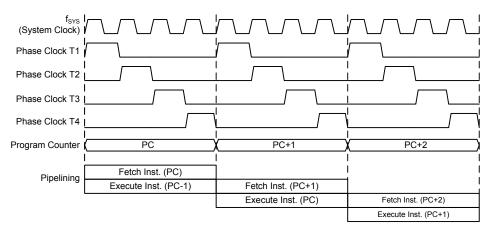


System Architecture

A key factor in the high-performance features of the Holtek range of microcontrollers is attributed to their internal system architecture. The device takes advantage of the usual features found within RISC microcontrollers providing increased speed of operation and Periodic performance. The pipelining scheme is implemented in such a way that instruction fetching and instruction execution are overlapped, hence instructions are effectively executed in one cycle, with the exception of branch or call instructions. An 8-bit wide ALU is used in practically all instruction set operations, which carries out arithmetic operations, logic operations, rotation, increment, decrement, branch decisions, etc. The internal data path is simplified by moving data through the Accumulator and the ALU. Certain internal registers are implemented in the Data Memory and can be directly or indirectly addressed. The simple addressing methods of these registers along with additional architectural features ensure that a minimum of external components is required to provide a functional I/O control system with maximum reliability and flexibility. This makes the device suitable for low-cost, high-volume production for controller applications.

Clocking and Pipelining

The main system clock, derived from an internal RC oscillator is subdivided into four internally generated non-overlapping clocks, T1~T4. The Program Counter is incremented at the beginning of the T1 clock during which time a new instruction is fetched. The remaining T2~T4 clocks carry out the decoding and execution functions. In this way, one T1~T4 clock cycle forms one instruction cycle. Although the fetching and execution of instructions takes place in consecutive instruction cycles, the pipelining structure of the microcontroller ensures that instructions are effectively executed in one instruction cycle. The exception to this are instructions where the contents of the Program Counter are changed, such as subroutine calls or jumps, in which case the instruction will take one more instruction cycle to execute.

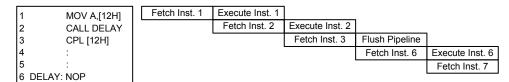


System Clock and Pipelining

For instructions involving branches, such as jump or call instructions, two machine cycles are required to complete instruction execution. An extra cycle is required as the program takes one cycle to first obtain the actual jump or call address and then another cycle to actually execute the branch. The requirement for this extra cycle should be taken into account by programmers in timing sensitive applications.

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Instruction Fetching

Program Counter

During program execution, the Program Counter is used to keep track of the address of the next instruction to be executed. It is automatically incremented by one each time an instruction is executed except for instructions, such as "JMP" or "CALL" that demand a jump to a non-consecutive Program Memory address. Only the lower 8 bits, known as the Program Counter Low Register, are directly addressable by the application program.

When executing instructions requiring jumps to non-consecutive addresses such as a jump instruction, a subroutine call, interrupt or reset, etc., the microcontroller manages program control by loading the required address into the Program Counter. For conditional skip instructions, once the condition has been met, the next instruction, which has already been fetched during the present instruction execution, is discarded and a dummy cycle takes its place while the correct instruction is obtained.

Program Counter						
High Byte	Low Byte (PCL Register)					
PC10~PC8	PCL7~PCL0					

The lower byte of the Program Counter, known as the Program Counter Low register or PCL, is available for program control and is a readable and writeable register. By transferring data directly into this register, a short program jump can be executed directly, however, as only this low byte is available for manipulation, the jumps are limited to the present page of memory that is 256 locations. When such program jumps are executed it should also be noted that a dummy cycle will be inserted. Manipulating the PCL register may cause program branching, so an extra cycle is needed to pre-fetch.

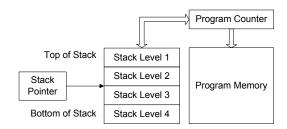
Stack

This is a special part of the memory which is used to save the contents of the Program Counter only. The stack is organized into 4 levels and neither part of the data nor part of the program space, and is neither readable nor writeable. The activated level is indexed by the Stack Pointer, and is neither readable nor writeable. At a subroutine call or interrupt acknowledge signal, the contents of the Program Counter are pushed onto the stack. At the end of a subroutine or an interrupt routine, signaled by a return instruction, RET or RETI, the Program Counter is restored to its previous value from the stack. After a device reset, the Stack Pointer will point to the top of the stack.

If the stack is full and an enabled interrupt takes place, the interrupt request flag will be recorded but the acknowledge signal will be inhibited. When the Stack Pointer is decremented, by RET or RETI, the interrupt will be serviced. This feature prevents stack overflow allowing the programmer to use the structure more easily. However, when the stack is full, a CALL subroutine instruction can still be executed which will result in a stack overflow. Precautions should be taken to avoid such cases which might cause unpredictable program branching. If the stack is overflow, the first Program Counter saved in the stack will be lost.

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Arithmetic and Logic Unit - ALU

The arithmetic-logic unit or ALU is a critical area of the microcontroller that carries out arithmetic and logic operations of the instruction set. Connected to the main microcontroller data bus, the ALU receives related instruction codes and performs the required arithmetic or logical operations after which the result will be placed in the specified register. As these ALU calculation or operations may result in carry, borrow or other status changes, the status register will be correspondingly updated to reflect these changes. The ALU supports the following functions:

- · Arithmetic operations: ADD, ADDM, ADC, ADCM, SUB, SUBM, SBC, SBCM, DAA
- Logic operations: AND, OR, XOR, ANDM, ORM, XORM, CPL, CPLA
- Rotation: RRA, RR, RRCA, RRC, RLA, RL, RLCA, RLC
- Increment and Decrement: INCA, INC, DECA, DEC
- Branch decision: JMP, SZ, SZA, SNZ, SIZ, SDZ, SIZA, SDZA, CALL, RET, RETI

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Flash Program Memory

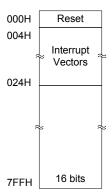
The Program Memory is the location where the user code or program is stored. For this device the Program Memory is Flash type, which means it can be programmed and re-programmed a large number of times, allowing the user the convenience of code modification on the same device. By using the appropriate programming tools, this Flash device offers users the flexibility to conveniently debug and develop their applications while also offering a means of field programming and updating.

Structure

The Program Memory has a capacity of $2K \times 16$ bits. The Program Memory is addressed by the Program Counter and also contains data, table information and interrupt entries. Table data, which can be setup in any location within the Program Memory, is addressed by a separate table pointer register.

Special Vectors

Within the Program Memory, certain locations are reserved for the reset and interrupts. The location 000H is reserved for use by the device reset for program initialisation. After a device reset is initiated, the program will jump to this location and begin execution.



Program Memory Structure

Look-up Table

Any location within the Program Memory can be defined as a look-up table where programmers can store fixed data. To use the look-up table, the table pointer must first be setup by placing the address of the look up data to be retrieved in the table pointer registers, TBLP and TBHP. These registers define the total address of the look-up table.

After setting up the table pointer, the table data can be retrieved from the Program Memory using the "TABRD[m]" or "TABRDL[m]" instructions, respectively. When the instruction is executed, the lower order table byte from the Program Memory will be transferred to the user defined Data Memory register [m] as specified in the instruction. The higher order table data byte from the Program Memory will be transferred to the TBLH special register. Any unused bits in this transferred higher order byte will be read as "0".

The accompanying diagram illustrates the addressing data flow of the look-up table.

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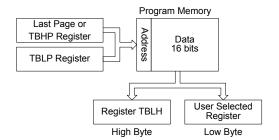


Table Program Example

The following example shows how the table pointer and table data is defined and retrieved from the microcontroller. This example uses raw table data located in the Program Memory which is stored there using the ORG statement. The value at this ORG statement is "700H" which refers to the start address of the last page within the 2K words Program Memory of the device. The table pointer is setup here to have an initial value of "06H". This will ensure that the first data read from the data table will be at the Program Memory address "706H" or 6 locations after the start of the TBHP specified page. Note that the value for the table pointer is referenced to the first address specified by the TBHP and TBLP registers if the "TABRD [m]" instruction is being used. The high byte of the table data which in this case is equal to zero will be transferred to the TBLH register automatically when the "TABRD [m]" instruction is executed.

Because the TBLH register is a read-only register and cannot be restored, care should be taken to ensure its protection if both the main routine and Interrupt Service Routine use table read instructions. If using the table read instructions, the Interrupt Service Routines may change the value of the TBLH and subsequently cause errors if used again by the main routine. As a rule it is recommended that simultaneous use of the table read instructions should be avoided. However, in situations where simultaneous use cannot be avoided, the interrupts should be disabled prior to the execution of any main routine table-read instructions. Note that all table related instructions require two instruction cycles to complete their operation.

Table Read Program Example

```
tempreg1 db ?
                  ; temporary register #1
tempreg2 db ?
                   ; temporary register #2
                   ; initialise low table pointer - note that this address is referenced
mov a,06h
mov tblp,a
                   ; to the last page or specific page
mov a,07h
                   ; initialise high table pointer
mov tbhp, a
tabrd tempreg1
                   ; transfers value in table referenced by table pointer
                   ; data at program memory address "706H" transferred to tempreg1 and TBLH
dec tblp
                   ; reduce value of table pointer by one
tabrd tempreg2
                   ; transfers value in table referenced by table pointer
                   ; data at program memory address "705H" transferred to tempreg2 and TBLH
                   ; in this example the data "1AH" is transferred to tempreg1 and data "OFH"
                   ; to register tempreg2, the value OOH will be transferred to the high
                   ; byte register TBLH
org 700h
                   ; sets initial address of program memory
dc 00Ah, 00Bh, 00Ch, 00Dh, 00Eh, 00Fh, 01Ah, 01Bh
```

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In Circuit Programming

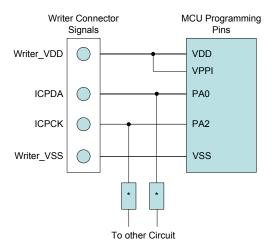
The provision of Flash type Program Memory provides the user with a means of convenient and easy upgrades and modifications to their programs on the same device. As an additional convenience, Holtek has provided a means of programming the microcontroller in-circuit using a 4-pin interface. This provides manufacturers with the possibility of manufacturing their circuit boards complete with a programmed or un-programmed microcontroller, and then programming or upgrading the program at a later stage. This enables product manufacturers to easily keep their manufactured products supplied with the latest program releases without removal and re-insertion of the device.

The Holtek Flash MCU to Writer Programming Pin correspondence table is as follows:

Holtek Writer Pins	MCU Programming Pins	Function		
ICPDA	PA0	Programming Serial Data/Address		
ICPCK	PA2	Programming Clock		
VDD	VDD&VPPI	Power Supply		
VSS	VSS	Ground		

The Program Memory and EEPROM data memory can both be programmed serially in-circuit using this 4-wire interface. Data is downloaded and uploaded serially on a single pin with an additional line for the clock. Two additional lines are required for the power supply. The technical details regarding the in-circuit programming of the device are beyond the scope of this document and will be supplied in supplementary literature.

During the programming process, the user must take care of the ICPDA and ICPCK pins for data and clock programming purpose to ensure that no other outputs are connected to these two pins.



Note: * may be resistor or capacitor. The resistance of * must be greater than $1k\Omega$ or the capacitance of * must be less than 1nF.

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On-Chip Debug Support - OCDS

The device has an EV chip named BH67V2132, which is used to emulate the BH67F2132 device. This EV chip device also provides an "On-Chip Debug" function to debug the real MCU device during the development process. The EV chip and the real MCU device are almost functionally compatible except for the "On-Chip Debug" function. Users can use the EV chip device to emulate the real chip device behavior by connecting the OCDSDA and OCDSCK pins to the Holtek HT-IDE development tools. The OCDSDA pin is the OCDS Data/Address input/output pin while the OCDSCK pin is the OCDS clock input pin. When users use the EV chip for debugging, other functions which are shared with the OCDSDA and OCDSCK pins in the device will have no effect in the EV chip. However, the two OCDS pins which are pin-shared with the ICP programming pins are still used as the Flash Memory programming pins for ICP. For more detailed OCDS information, refer to the corresponding document named "Holtek e-Link for 8-bit MCU OCDS User's Guide".

Holtek e-Link Pins	EV Chip Pins	Pin Description		
OCDSDA	OCDSDA	On-chip Debug Support Data/Address input/output		
OCDSCK OCDSCK		On-chip Debug Support Clock input		
VDD	VDD&VPPI	Power Supply		
GND	VSS	Ground		

RAM Data Memory

The Data Memory is a volatile area of 8-bit wide RAM internal memory and is the location where temporary information is stored.

Categorised into two types, the first of these is an area of RAM, known as the Special Purpose Data Memory. Here are located special function registers which have fixed locations and are necessary for correct operation of the device. Many of these registers can be read from and written to directly under program control, however, some remain protected from user manipulation. The second area of Data Memory is known as the General Purpose Data Memory, which is reserved for general purpose use. All locations within this area are read and write accessible under program control. There is an area of the Data Memory is reserved for the LCD Display Memory. This area is mapped directly to the LCD display so data written into this memory area will directly affect the displayed data. The addresses of the LCD Memory area overlap those in the area of 80H~95H of Bank 4.

Switching between the different Data Memory banks can be achieved by properly setting the Data Memory Pointers to correct value.

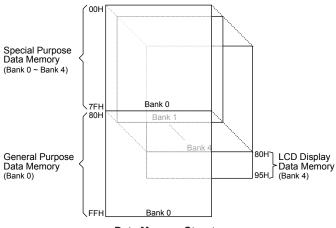
Structure

The overall Data Memory is subdivided into several banks, all of which are implemented in 8-bit wide RAM. The Special Purpose Data Memory registers are accessible in all banks, with the exception of the EEC register at address 40H, which is only accessible in Bank 1. Switching between the different Data Memory banks is achieved by setting the Data Memory Bank Pointer to the correct value. The start address of the Data Memory for the device is the address 00H.

Special Purpose Data Memory		ral Purpose a Memory	LCD Display Data Memory
Located Banks	Capacity	Address	Address
Bank 0~4	128×8	Bank 0: 80H~FFH	Bank 4: 80H~95H

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Data Memory Structure

General Purpose Data Memory

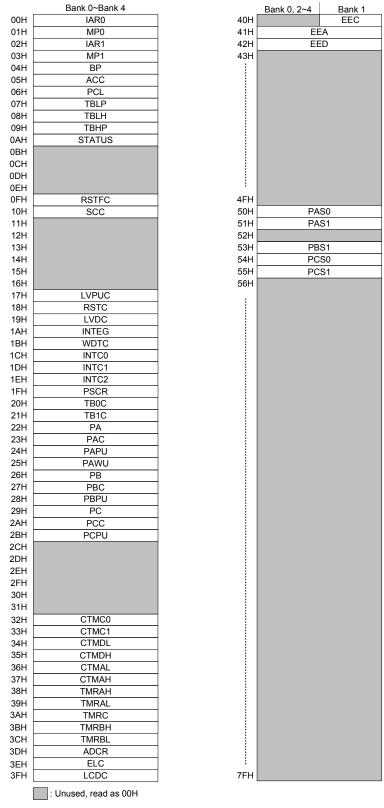
All microcontroller programs require an area of read/write memory where temporary data can be stored and retrieved for use later. It is this area of RAM memory that is known as General Purpose Data Memory. This area of Data Memory is fully accessible by the user programing for both reading and writing operations. By using the bit operation instructions individual bits can be set or reset under program control giving the user a large range of flexibility for bit manipulation in the Data Memory.

Special Purpose Data Memory

This area of Data Memory is where registers, necessary for the correct operation of the microcontroller, are stored. Most of the registers are both readable and writeable but some are protected and are readable only, the details of which are located under the relevant Special Function Register section. Note that for locations that are unused, any read instruction to these addresses will return the value "00H".

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Special Purpose Data Memory Structure



Special Function Register Description

Most of the Special Function Register details will be described in the relevant functional section. However, several registers require a separate description in this section.

Indirect Addressing Registers - IAR0, IAR1

The Indirect Addressing Registers, IAR0 and IAR1, although having their locations in normal RAM register space, do not actually physically exist as normal registers. The method of indirect addressing for RAM data manipulation uses these Indirect Addressing Registers and Memory Pointers, in contrast to direct memory addressing, where the actual memory address is specified. Actions on the IAR0 and IAR1 registers will result in no actual read or write operation to these registers but rather to the memory location specified by their corresponding Memory Pointers, MP0 or MP1. Acting as a pair, IAR0 and MP0 can together access data from Bank 0 while the IAR1 and MP1 register pair can access data from any bank. As the Indirect Addressing Registers are not physically implemented, reading the Indirect Addressing Registers indirectly will return a result of "00H" and writing to the registers indirectly will result in no operation.

Memory Pointers - MP0, MP1

Two Memory Pointers, known as MP0 and MP1 are provided. These Memory Pointers are physically implemented in the Data Memory and can be manipulated in the same way as normal registers providing a convenient way with which to address and track data. When any operation to the relevant Indirect Addressing Registers is carried out, the actual address that the microcontroller is directed to is the address specified by the related Memory Pointer. MP0, together with Indirect Addressing Register, IAR0, are used to access data from Bank 0, while MP1 and IAR1 are used to access data from all banks according to BP register. Direct Addressing can only be used within Bank 0, all other Banks must be addressed indirectly using MP1 and IAR1.

The following example shows how to clear a section of four Data Memory locations already defined as locations adres1 to adres4.

Indirect Addressing Program Example

```
data .section 'data
adres1 db?
adres2 db?
adres3 db?
adres4 db?
       db?
block
code .section at 0 'code'
org 00h
start:
     mov a,04h
                         ; setup size of block
    mov block, a
    mov a, offset adres1 ; Accumulator loaded with first RAM address
                         ; setup memory pointer with first RAM address
     mov mp0,a
loop:
     clr IAR0
                         ; clear the data at address defined by mp0
     inc mp0
                         ; increment memory pointer
     sdz block
                         ; check if last memory location has been cleared
     jmp loop
continue:
```

The important point to note here is that in the example shown above, no reference is made to specific Data Memory addresses.

Bank Pointer - BP

For this device, the Data Memory is divided into five banks, Bank $0 \sim Bank4$. Selecting the required Data Memory area is achieved using the Bank Pointer. Bit $0\sim Bit\ 2$ of the Bank Pointer is used to select Data Memory Bank $0 \sim Bank\ 4$.

The Data Memory is initialised to Bank 0 after a reset, except for a WDT time-out reset in IDLE or SLEEP Mode, in which case, the Data Memory bank remains unaffected. It should be noted that the Special Purpose Data Memory is not affected by the bank selection, which means that the Special Function Registers can be accessed from within any bank. Directly addressing the Data Memory will always result in Bank 0 being accessed irrespective of the value of the Bank Pointer. Accessing data from other Banks except Bank 0 must be implemented using Indirect Addressing.

BP Register

Bit	7	6	5	4	3	2	1	0
Name	_	_	_	_	_	DMBP2	DMBP1	DMBP0
R/W	_	_	_	_	_	R/W	R/W	R/W
POR	_	_	_	_	_	0	0	0

Bit 7~3 Unimplemented, read as "0"

Bit 2~0 **DMBP2~DMBP0**: Data Memory Bank Selection

000: Bank 0 001: Bank 1 010: Bank 2 011: Bank 3 100: Bank 4 Others: Undefined

Accumulator - ACC

The Accumulator is central to the operation of any microcontroller and is closely related with operations carried out by the ALU. The Accumulator is the place where all intermediate results from the ALU are stored. Without the Accumulator it would be necessary to write the result of each calculation or logical operation such as addition, subtraction, shift, etc., to the Data Memory resulting in higher programming and timing overheads. Data transfer operations usually involve the temporary storage function of the Accumulator; for example, when transferring data between one user-defined register and another, it is necessary to do this by passing the data through the Accumulator as no direct transfer between two registers is permitted.

Program Counter Low Register - PCL

To provide additional program control functions, the low byte of the Program Counter is made accessible to programmers by locating it within the Special Purpose area of the Data Memory. By manipulating this register, direct jumps to other program locations are easily implemented. Loading a value directly into this PCL register will cause a jump to the specified Program Memory location, however, as the register is only 8-bit wide, only jumps within the current Program Memory page are permitted. When such operations are used, note that a dummy cycle will be inserted.

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Look-up Table Registers - TBLP, TBHP, TBLH

These three special function registers are used to control operation of the look-up table which is stored in the Program Memory. TBLP and TBHP are the table pointers and indicate the location where the table data is located. Their value must be setup before any table read commands are executed. Their value can be changed, for example using the "INC" or "DEC" instruction, allowing for easy table data pointing and reading. TBLH is the location where the high order byte of the table data is stored after a table read data instruction has been executed. Note that the lower order table data byte is transferred to a user defined location.

Status Register - STATUS

This 8-bit register contains the zero flag (Z), carry flag (C), auxiliary carry flag (AC), overflow flag (OV), power down flag (PDF), and watchdog time-out flag (TO). These arithmetic/logical operation and system management flags are used to record the status and operation of the microcontroller.

With the exception of the TO and PDF flags, bits in the status register can be altered by instructions like most other registers. Any data written into the status register will not change the TO or PDF flag. In addition, operations related to the status register may give different results due to the different instruction operations. The TO flag can be affected only by a system power-up, a WDT time-out or by executing the "CLR WDT" or "HALT" instruction. The PDF flag is affected only by executing the "HALT" or "CLR WDT" instruction or during a system power-up.

The Z, OV, AC and C flags generally reflect the status of the latest operations.

- C is set if an operation results in a carry during an addition operation or if a borrow does not take place during a subtraction operation; otherwise C is cleared. C is also affected by a rotate through carry instruction.
- AC is set if an operation results in a carry out of the low nibbles in addition, or no borrow from the high nibble into the low nibble in subtraction; otherwise AC is cleared.
- Z is set if the result of an arithmetic or logical operation is zero; otherwise Z is cleared.
- OV is set if an operation results in a carry into the highest-order bit but not a carry out of the highest-order bit, or vice versa; otherwise OV is cleared.
- PDF is cleared by a system power-up or executing the "CLR WDT" instruction. PDF is set by executing the "HALT" instruction.
- TO is cleared by a system power-up or executing the "CLR WDT" or "HALT" instruction. TO is set by a WDT time-out.

In addition, on entering an interrupt sequence or executing a subroutine call, the status register will not be pushed onto the stack automatically. If the contents of the status registers are important and if the subroutine can corrupt the status register, precautions must be taken to correctly save it.

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• STATUS Register

Bit	7	6	5	4	3	2	1	0
Name	_	_	TO	PDF	OV	Z	AC	С
R/W	_	_	R	R	R/W	R/W	R/W	R/W
POR	_	_	0	0	Х	Х	Х	Х

"x": unknown

Bit 7~6 Unimplemented, read as "0"

Bit 5 **TO**: Watchdog Time-out flag

0: After power up or executing the "CLR WDT" or "HALT" instruction

1: A watchdog time-out occurred.

Bit 4 **PDF**: Power down flag

0: After power up or executing the "CLR WDT" instruction

1: By executing the "HALT" instruction

Bit 3 **OV**: Overflow flag

0: No overflow

1: An operation results in a carry into the highest-order bit but not a carry out of the highest-order bit or vice versa.

Bit 2 Z: Zero flag

0: The result of an arithmetic or logical operation is not zero

1: The result of an arithmetic or logical operation is zero

Bit 1 AC: Auxiliary flag

0: No auxiliary carry

1: An operation results in a carry out of the low nibbles in addition, or no borrow from the high nibble into the low nibble in subtraction

Bit 0 C: Carry flag

0: No carry-out

1: An operation results in a carry during an addition operation or if a borrow does not take place during a subtraction operation

C is also affected by a rotate through carry instruction.



EEPROM Data Memory

The device contains an area of internal EEPROM Data Memory. EEPROM is by its nature a non-volatile form of re-programmable memory, with data retention even when its power supply is removed. By incorporating this kind of data memory, a whole new host of application possibilities are made available to the designer. The availability of EEPROM storage allows information such as product identification numbers, calibration values, specific user data, system setup data or other product information to be stored directly within the product microcontroller. The process of reading and writing data to the EEPROM memory has been reduced to a very trivial affair.

EEPROM Data Memory Structure

The EEPROM Data Memory capacity is 128×8 bits. Unlike the Program Memory and Data Memory, the EEPROM Data Memory is not directly mapped and is therefore not directly accessible in the same way as the other types of memory. Read and Write operations to the EEPROM are carried out in single byte operations using an address and data register in Bank 0 and a single control register in Bank 1.

EEPROM Registers

Three registers control the overall operation of the internal EEPROM Data Memory. These are the address register, EEA, the data register, EED and a single control register, EEC. As both the EEA and EED registers are located in Bank 0, they can be directly accessed in the same way as any other Special Function Register. The EEC register however, being located in Bank 1, cannot be directly addressed directly and can only be read from or written to indirectly using the MP1 Memory Pointer and Indirect Addressing Register, IAR1. Because the EEC control register is located at address 40H in Bank 1, the MP1 Memory Pointer must first be set to the value 40H and the Bank Pointer register, BP, set to the value, 01H, before any operations on the EEC register are executed.

Register	Bit										
Name	7	6	5	4	3	2	1	0			
EEA	_	EEA6	EEA5	EEA4	EEA3	EEA2	EEA1	EEA0			
EED	D7	D6	D5	D4	D3	D2	D1	D0			
EEC	_	_	_	_	WREN	WR	RDEN	RD			

EEPROM Control Register List

EEA Register

Bit	7	6	5	4	3	2	1	0
Name	_	EEA6	EEA5	EEA4	EEA3	EEA2	EEA1	EEA0
R/W	_	R/W						
POR	_	0	0	0	0	0	0	0

Bit 7 Unimplemented, read as "0"

Bit 6~0 Data EEPROM address

Data EEPROM address bit 6~bit 0

· EED Register

Bit	7	6	5	4	3	2	1	0
Name	D7	D6	D5	D4	D3	D2	D1	D0
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
POR	0	0	0	0	0	0	0	0

Bit 7~0 Data EEPROM data

Data EEPROM data bit 7~bit 0

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BH67F2132 Ultra-Low Voltage R to F Flash MCU

• EEC Register

Bit	7	6	5	4	3	2	1	0
Name	_	_	_	_	WREN	WR	RDEN	RD
R/W	_	_	_	_	R/W	R/W	R/W	R/W
POR	_	_	_	_	0	0	0	0

Bit 7~4 Unimplemented, read as "0"

Bit 3 WREN: Data EEPROM Write Enable

0: Disable 1: Enable

This is the Data EEPROM Write Enable Bit which must be set high before Data EEPROM write operations are carried out. Clearing this bit to zero will inhibit Data EEPROM write operations.

Bit 2 WR: EEPROM Write Control

0: Write cycle has finished

1: Activate a write cycle

This is the Data EEPROM Write Control Bit and when set high by the application program will activate a write cycle. This bit will be automatically reset to zero by the hardware after the write cycle has finished. Setting this bit high will have no effect if the WREN has not first been set high.

Bit 1 RDEN: Data EEPROM Read Enable

0: Disable 1: Enable

This is the Data EEPROM Read Enable Bit which must be set high before Data EEPROM read operations are carried out. Clearing this bit to zero will inhibit Data EEPROM read operations.

Bit 0 **RD**: EEPROM Read Control

0: Read cycle has finished

1: Activate a read cycle

This is the Data EEPROM Read Control Bit and when set high by the application program will activate a read cycle. This bit will be automatically reset to zero by the hardware after the read cycle has finished. Setting this bit high will have no effect if the RDEN has not first been set high.

Note: 1. The WREN, WR, RDEN and RD cannot be set to "1" at the same time in one instruction. The WR and RD cannot be set to "1" at the same time.

- 2. Ensure that the f_{SUB} clock is stable before executing the write operation.
- 3. Ensure that the write operation is totally complete before changing the EEC register content.

Reading Data from the EEPROM

To read data from the EEPROM, The EEPROM address of the data to be read must then be placed in the EEA register. Then the read enable bit, RDEN, in the EEC register must first be set high to enable the read function. If the RD bit in the EEC register is now set high, a read cycle will be initiated. Setting the RD bit high will not initiate a read operation if the RDEN bit has not been set. When the read cycle terminates, the RD bit will be automatically cleared to zero, after which the data can be read from the EED register. The data will remain in the EED register until another read or write operation is executed. The application program can poll the RD bit to determine when the data is valid for reading.

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Writing Data to the EEPROM

To write data to the EEPROM, the EEPROM address of the data to be written must first be placed in the EEA register and the data placed in the EED register. Then the write enable bit, WREN, in the EEC register must first be set high to enable the write function. After this, the WR bit in the EEC register must be immediately set high to initiate a write cycle. These two instructions must be executed in two consecutive instruction cycles. The global interrupt bit EMI should also first be cleared before implementing any write operations, and then set again after the write cycle has started. Note that setting the WR bit high will not initiate a write cycle if the WREN bit has not been set. As the EEPROM write cycle is controlled using an internal timer whose operation is asynchronous to microcontroller system clock, a certain time will elapse before the data will have been written into the EEPROM. Detecting when the write cycle has finished can be implemented either by polling the WR bit in the EEC register or by using the EEPROM interrupt. When the write cycle terminates, the WR bit will be automatically cleared to zero by the microcontroller, informing the user that the data has been written to the EEPROM. The application program can therefore poll the WR bit to determine when the write cycle has ended.

Write Protection

Protection against inadvertent write operation is provided in several ways. After the device is powered on, the Write enable bit in the control register will be cleared preventing any write operations. Also at power-on the Bank Pointer, BP, will be reset to zero, which means that Data Memory Bank 0 will be selected. As the EEPROM control register is located in Bank 1, this adds a further measure of protection against spurious write operations. During normal program operation, ensuring that the Write Enable bit in the control register is cleared will safeguard against incorrect write operations.

EEPROM Interrupt

The EEPROM write interrupt is generated when an EEPROM write cycle has ended. The EEPROM interrupt must first be enabled by setting the DEE bit in the relevant interrupt register. When an EEPROM write cycle ends, the DEF request flag will be set. If the global and EEPROM interrupts are enabled and the stack is not full, a jump to the EEPROM Interrupt vector will take place. When the interrupt is serviced the EEPROM interrupt flag will be automatically reset. More details can be obtained in the Interrupt section.

Programming Considerations

Care must be taken that data is not inadvertently written to the EEPROM. Protection can be enhanced by ensuring that the Write Enable bit is normally cleared to zero when not writing. Also the Bank Pointer could be normally cleared to zero as this would inhibit access to Bank 1 where the EEPROM control register exist. Although certainly not necessary, consideration might be given in the application program to the checking of the validity of new write data by a simple read back process. When writing data the WR bit must be set high immediately after the WREN bit has been set high, to ensure the write cycle executes correctly. The global interrupt bit EMI should also be cleared before a write cycle is executed and then re-enabled after the write cycle starts. Note that the device should not enter the IDLE or SLEEP mode until the EEPROM read or write operation is totally completed, otherwise, the EEPROM read or write operation will fail.

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Programming Examples

Reading data from the EEPROM - polling method

```
MOV A, EEPROM ADRES ; user defined address
MOV EEA, A
MOV A, 040H
                     ; setup memory pointer MP1
MOV MP1, A
                     ; MP1 points to EEC register
MOV A, 01H
                      ; setup Bank Pointer
MOV BP, A
SET IAR1.1
                     ; set RDEN bit, enable read operations
SET IAR1.0
                       ; start Read Cycle - set RD bit
BACK:
SZ IAR1.0
                     ; check for read cycle end
JMP BACK
                       ; disable EEPROM read if no more read operations are required
CLR IAR1
CLR BP
MOV A, EED
                       ; move read data to register
MOV READ DATA, A
```

Note: For each read operation, the address register should be re-specified followed by setting the RD bit high to activate a read cycle even if the target address is consecutive.

Writing Data to the EEPROM - polling method

```
MOV A, EEPROM ADRES ; user defined address
MOV EEA, A
MOV A, EEPROM DATA
                     ; user defined data
MOV EED, A
MOV A, 040H
                     ; setup memory pointer MP1
MOV MP1, A
                      ; MP1 points to EEC register
MOV A, 01H
                      ; setup Bank Pointer
MOV BP, A
                       ; BP points to data memory bank 1
CLR EMI
SET IAR1.3
                      ; set WREN bit, enable write operations
SET IAR1.2
                       ; start Write Cycle - set WR bit - executed immediately
                       ; after set WREN bit
SET EMI
BACK:
SZ IAR1.2
                     ; check for write cycle end
JMP BACK
CLR BP
```

Oscillator Configuration

The internal RC oscillator is a fully integrated system oscillator requiring no external components. The internal RC oscillator has a frequency of 32kHz, 64kHz or 128kHz determined by the configuration option. The oscillation frequency may vary with the power supply voltage, temperature and process variations.

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Operating Modes and System Clocks

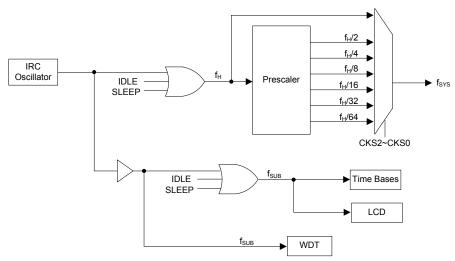
Present day applications require that their microcontrollers have high performance but often still demand that they consume as little power as possible, conflicting requirements that are especially true in battery powered portable applications. The fast clocks required for high performance will by their nature increase current consumption and of course vice-versa, lower speed clocks reduce current consumption. As Holtek has provided this device with different speed clock sources and the means to switch between them dynamically, the user can optimise the operation of their microcontroller to achieve the best performance/power ratio.

System Clocks

The device has one clock source for both the CPU and peripheral function operation. By providing the user with a wide range of clock options using configuration option and register programming, a clock system can be configured to obtain maximum application performance.

The main system clock comes from a high frequency $f_{\rm H}$ or a divided version of the $f_{\rm H}$ which is selected using the CKS2~CKS0 bits in the SCC register. The high speed system clock is sourced from the IRC oscillator.

There is an additional internal clock, the substitute clock, f_{SUB} , for the peripheral circuits. This internal clock is sourced by the IRC oscillator and has a fixed frequency of 32kHz.



Device Clock Configurations

System Operating Modes

There are three different modes of operation for the microcontroller, each one with its own special characteristics and which can be chosen according to the specific performance and power requirements of the application. There is one mode allowing normal operation of the microcontroller, the NORMAL Mode. The remaining two modes, the SLEEP and IDLE Mode are used when the microcontroller CPU is switched off to conserve power.

Operation Made	CPU	Regist	ter Setting	£	£	£	
Operation Mode	CFU	FIDEN	CKS2~CKS0	f _{SYS}	TH	t _{SUB}	
NORMAL Mode	On	Х	х	f _H ~f _H /64	On	On	
IDLE Mode	Off	1	х	On	On	On	
SLEEP Mode	Off	0	x	Off	Off	On/Off ^{Note}	

"x": Don't care

Note: The f_{SUB} clock can be switched on or off which is controlled by the WDT function being enabled or disabled in the SLEEP mode.

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NORMAL Mode

As the name suggests this is the main operating modes where the microcontroller has all of its functions operational and where the system clock is provided by the high speed oscillator. This mode operates allowing the microcontroller to operate normally with a clock source which comes from the IRC oscillator. The IRC oscillator output frequency will however first be divided by a ratio ranging from 1 to 64, the actual ratio being selected by the CKS2~CKS0 bits in the SCC register. Although a high speed oscillator is used, running the microcontroller at a divided clock ratio reduces the operating current.

SLEEP Mode

The SLEEP Mode is entered when an HALT instruction is executed and when the FIDEN bit in the SCC register is low. In the SLEEP mode the CPU will be stopped, and the LVD, LCD function will be disabled automatically. If the WDT function is enabled, the f_{SUB} clock will continue to operate. If the WDT function is disabled, the f_{SUB} clock will be stopped too.

IDLE Mode

The IDLE Mode is entered when an HALT instruction is executed and when the FIDEN bit in the SCC register is high. In the IDLE Mode the system oscillator will be inhibited from driving the CPU but continue to provide a clock source to keep some peripheral functions operational. In the IDLE Mode, the system oscillator will continue to run.

Control Registers

The SCC registers are used to control the internal clocks within the device.

SCC Register

ĺ	Bit	7	6	5	4	3	2	1	0
	Name	CKS2	CKS1	CKS0	_	_	_	FIDEN	_
	R/W	R/W	R/W	R/W	_	_	_	R/W	_
ĺ	POR	0	0	0	_	_	_	1	_

Bit 7~5 CKS2~CKS0: System clock selection

> 000: f_H 001: $f_H/2$ 010: $f_H/4$ $011: f_H/8$ 100: f_H/16 101: f_H/32 110: f_H/64 111: f_H

These three bits are used to select which clock is used as the system clock source. A divided version of the internal RC oscillator can also be chosen as the system clock source.

Bit 4~2 Unimplemented, read as "0"

Bit 1 FIDEN: IRC oscillator control when CPU is switched off

> 0: Disable 1: Enable

This bit is used to control whether the IRC oscillator is activated or stopped when the CPU is switched off by executing an HALT instruction. As the WDT clock f_{SUB} is sourced from the IRC oscillator, the IRC oscillator on/off is also controlled by the WDT function. If the FIDEN bit is cleared to zero but the WDT function is enabled in SLEEP mode, the f_{SUB} clock will also be enabled.

Unimplemented, read as "0" Bit 0

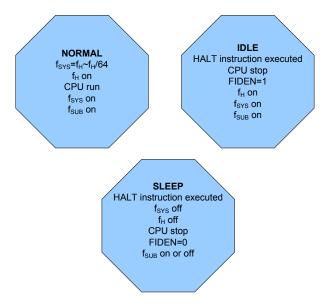
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Operating Mode Switching

The device can switch between operating modes dynamically allowing the user to select the best performance/power ratio for the present task in hand. In this way microcontroller operations that do not require high performance can be executed using slower clocks thus requiring less operating current and prolonging battery life in portable applications.

In simple terms, Mode Switching from the NORMAL Mode to the SLEEP/IDLE Mode is executed via the HALT instruction. When an HALT instruction is executed, whether the device enters the IDLE Mode or the SLEEP Mode is determined by the condition of the FIDEN bit in the SCC register.



Entering the SLEEP Mode

There is only one way for the device to enter the SLEEP Mode and that is to execute the "HALT" instruction in the application program with the FIDEN bit in SCC register equal to "0". When this instruction is executed under the conditions described above, the following will occur:

- The system clock will be stopped and the application program will stop at the "HALT" instruction.
- The Data Memory contents and registers will maintain their present condition.
- The WDT will be cleared and resume counting as the WDT is enabled. If the WDT is disabled then WDT will be cleared and stopped.
- The I/O ports will maintain their present conditions.
- In the status register, the Power Down flag, PDF, will be set and the Watchdog time-out flag, TO, will be cleared.

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Entering the IDLE Mode

There is only one way for the device to enter the IDLE Mode and that is to execute the "HALT" instruction in the application program with the FIDEN bit in SCC register equal to "1". When this instruction is executed under the conditions described above, the following will occur:

- The system clock, the f_H clock and the f_{SUB} clock will be on and the application program will stop at the "HALT" instruction.
- The Data Memory contents and registers will maintain their present condition.
- The WDT will be cleared and resume counting as the WDT is enabled. If the WDT is disabled then WDT will be cleared and stopped.
- The I/O ports will maintain their present conditions.
- In the status register, the Power Down flag, PDF, will be set and the Watchdog time-out flag, TO, will be cleared.

Standby Current Considerations

As the main reason for entering the SLEEP or IDLE Mode is to keep the current consumption of the device to as low a value as possible, there are other considerations which must also be taken into account by the circuit designer if the power consumption is to be minimised. Special attention must be made to the I/O pins on the device. All high-impedance input pins must be connected to either a fixed high or low level as any floating input pins could create internal oscillations and result in increased current consumption. This also applies to devices which have different package types, as there may be unbonbed pins. These must either be setup as outputs or if setup as inputs must have pull-high resistors connected.

Care must also be taken with the loads, which are connected to I/O pins, which are setup as outputs. These should be placed in a condition in which minimum current is drawn or connected only to external circuits that do not draw current, such as other CMOS inputs.

Wake-up

To minimise power consumption the device can enter the SLEEP or any IDLE Mode, where the CPU will be switched off. However, when the device is woken up again, it will take a considerable time for the original system oscillator to restart, stabilise and allow normal operation to resume.

After the system enters the SLEEP or IDLE Mode, it can be woken up from one of various sources listed as follows:

- · An external falling edge on Port A
- · An external reset
- · A system interrupt
- A WDT overflow

When the device executes the "HALT" instruction, it will enter the IDLE or SLEEP mode and the PDF flag will be set high. The PDF flag is cleared to 0 if the device experiences a system power-up or executes the clear Watchdog Timer instruction.

If the system is woken up by an external reset, the device will experience a full system reset, however, if the device is woken up by a WDT overflow, a Watchdog Timer reset will be initiated. Although both of these wake-up methods will initiate a reset operation, the actual source of the wake-up can be determined by examining the TO and PDF flags. The TO flag is set high if a WDT time-out occurs, and causes a wake-up that only resets the Program Counter and Stack Pointer, the other flags remain in their original status.

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Each pin on Port A can be setup using the PAWU register to permit a negative transition on the pin to wake-up the system. When a Port A pin wake-up occurs, the program will resume execution at the instruction following the "HALT" instruction. If the system is woken up by an interrupt, then two possible situations may occur. The first is where the related interrupt is disabled or the interrupt is enabled but the stack is full, in which case the program will resume execution at the instruction following the "HALT" instruction. In this situation, the interrupt which woke-up the device will not be immediately serviced, but will rather be serviced later when the related interrupt is finally enabled or when a stack level becomes free. The other situation is where the related interrupt is enabled and the stack is not full, in which case the regular interrupt response takes place. If an interrupt request flag is set high before entering the SLEEP or IDLE Mode, the wake-up function of the related interrupt will be disabled.

Watchdog Timer

The Watchdog Timer is provided to prevent program malfunctions or sequences from jumping to unknown locations, due to certain uncontrollable external events such as electrical noise.

Watchdog Timer Clock Source

The Watchdog Timer clock source is provided by the internal f_{SUB} clock which is supplied by the IRC oscillator. The Watchdog Timer source clock is then subdivided by a ratio of 2^8 to 2^{18} to give longer timeouts, the actual value being chosen using the WS2~WS0 bits in the WDTC register. The f_{SUB} clock has a fixed frequency of 32kHz.

Watchdog Timer Control Register

A single register, WDTC, controls the required timeout period as well as the enable/disable operation. The WDTC is set to 01010011B at device reset except WDT time-out in IDLE or SLEEP mode.

WDTC Register

Bit	7	6	5	4	3	2	1	0
Name	WE4	WE3	WE2	WE1	WE0	WS2	WS1	WS0
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
POR	0	1	0	1	0	0	1	1

Bit 7~3 **WE4~WE0**: WDT function enable/disable control

10101: Disable 01010: Enable Others: Reset MCU

When these bits are changed by the environmental noise or software setting to reset the microcontroller, the reset operation will be activated after a delay time, tsreset and the WRF bit in the RSTFC register will be set high.

Bit 2~0 WS2~WS0: WDT time-out period selection

 $\begin{array}{l} 000:\ 2^8/f_{SUB} \\ 001:\ 2^{10}/f_{SUB} \\ 010:\ 2^{12}/f_{SUB} \\ 011:\ 2^{14}/f_{SUB} \\ 100:\ 2^{15}/f_{SUB} \\ 101:\ 2^{16}/f_{SUB} \\ 111:\ 2^{18}/f_{SUB} \\ \end{array}$

These three bits determine the division ratio of the Watchdog Timer source clock, which in turn determines the timeout period.

RSTFC Register

Bit 3

Bit	7	6	5	4	3	2	1	0
Name	_	_	_	_	RSTF	_	_	WRF
R/W	_	_	_	_	R/W	_	_	R/W
POR	_	_	_	_	0	_	_	0

Bit 7~4 Unimplemented, read as "0"

RSTF: RSTC register software reset flag

Described elsewhere.

Bit 2~1 Unimplemented, read as "0"

Bit 0 WRF: WDTC register software reset flag

0: Not occur
1: Occurred

This bit is set high by the WDT Control register software reset and cleared by the application program. Note that this bit can only be cleared to zero by the application program.

Watchdog Timer Operation

The Watchdog Timer operates by providing a device reset when its timer overflows. This means that in the application program and during normal operation the user has to strategically clear the Watchdog Timer before it overflows to prevent the Watchdog Timer from executing a reset. This is done using the clear watchdog instructions. If the program malfunctions for whatever reason, jumps to an unknown location, or enters an endless loop, these clear instructions will not be executed in the correct manner, in which case the Watchdog Timer will overflow and reset the device. With regard to the Watchdog Timer enable/disable function, there are five bits, WE4~WE0, in the WDTC register to offer enable/disable and reset control of the Watchdog Timer. The WE4~WE0 values can determine which mode the WDT operates in. The WDT function will be disabled when the WE4~WE0 bits are set to a value of 10101B. The WDT function will be enabled if the WE4~WE0 bits value is equal to 01010B. If the WE4~WE0 bits are set to any other values except 01010B and 10101B by the environmental noise or software setting, it will reset the device after a delay time, t_{SRESET}. After power on these bits will have the value of 01010B.

WE4~WE0 Bits	WDT Function
10101B	Disable
01010B	Enable
Any other values	Reset MCU

Watchdog Timer Enable/Disable Control

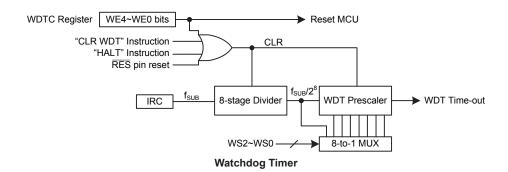
Under normal program operation, a Watchdog Timer time-out will initialise a device reset and set the status bit TO. However, if the system is in the SLEEP or IDLE Mode, when a Watchdog Timer time-out occurs, the PDF bit in the STATUS register remains high and the TO bit in the STATUS register will be set high and only the Program Counter and Stack Pointer will be reset. Four methods can be adopted to clear the contents of the Watchdog Timer. The first is a WDTC software reset, which means a certain value except 01010B and 10101B written into the WE4~WE0 bit filed, the second is using the Watchdog Timer software clear instruction, the third is via a HALT instruction and the last is an external hardware reset which means a low level on the external reset pin.

There is only one method of using software instruction to clear the Watchdog Timer. That is to use the single "CLR WDT" instruction to clear the WDT.

The maximum time out period is when the 2¹⁸ division ratio is selected. As an example, with a 32kHz clock source, this will give a maximum watchdog period of around 8 second for the 2¹⁸ division ratio, and a minimum timeout of 8ms for the 2⁸ division ratio.

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Reset and Initialisation

A reset function is a fundamental part of any microcontroller ensuring that the device can be set to some predetermined condition irrespective of outside parameters. The most important reset condition is after power is first applied to the microcontroller. In this case, internal circuitry will ensure that the microcontroller, after a short delay, will be in a well defined state and ready to execute the first program instruction. After this power-on reset, certain important internal registers will be set to defined states before the program commences. One of these registers is the Program Counter, which will be reset to zero forcing the microcontroller to begin program execution from the lowest Program Memory address.

In addition to the power-on reset, situations may arise where it is necessary to forcefully apply a reset condition when the device is running. One example of this is where after power has been applied and the device is already running, the $\overline{\text{RES}}$ line is forcefully pulled low. In such a case, known as a normal operation reset, some of the registers remain unchanged allowing the device to proceed with normal operation after the reset line is allowed to return high.

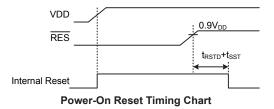
Another type of reset is when the Watchdog Timer overflows and resets the microcontroller. All types of reset operations result in different register conditions being setup.

Reset Functions

There are several ways in which a microcontroller reset can occur, through events occurring both internally and externally.

Power-on Reset

The most fundamental and unavoidable reset is the one that occurs after power is first applied to the microcontroller. As well as ensuring that the Program Memory begins execution from the first memory address, a power-on reset also ensures that certain other registers are preset to known conditions. All the I/O port and port control registers will power up in a high condition ensuring that all pins will be first set to inputs.



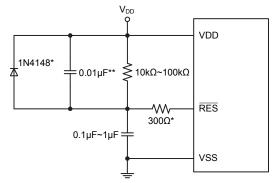


RES Pin Reset

Although the microcontroller has an internal RC reset function, if the VDD power supply rise time is not fast enough or does not stabilise quickly at power-on, the internal reset function may be incapable of providing proper reset operation. For this reason it is recommended that an external RC network is connected to the $\overline{\text{RES}}$ pin, whose additional time delay will ensure that the $\overline{\text{RES}}$ pin remains low for an extended period to allow the power supply to stabilise. During this time delay, normal operation of the microcontroller will be inhibited. After the $\overline{\text{RES}}$ line reaches a certain voltage value, the reset delay time t_{RSTD} is invoked to provide an extra delay time after which the microcontroller will begin normal operation. The abbreviation SST in the figures stands for System Start-up Timer.

For most applications a resistor connected between VDD and the \overline{RES} pin and a capacitor connected between VSS and the \overline{RES} pin will provide a suitable external reset circuit. Any wiring connected to the \overline{RES} pin should be kept as short as possible to minimise any stray noise interference.

For applications that operate within an environment where more noise is present the Enhanced Reset Circuit shown is recommended.

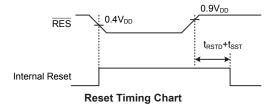


Note: * It is recommended that this component is added for added ESD protection.

** It is recommended that this component is added in environments where power line noise is significant.

External RES Circuit

Pulling the $\overline{\text{RES}}$ Pin low using external hardware will also execute a device reset. In this case, as in the case of other resets, the Program Counter will reset to zero and program execution initiated from this point.



There is an internal reset control register, RSTC, which is used to provide a reset when the device operates abnormally due to the environmental noise interference. If the content of the RSTC register is set to any value other than 01010101B or 10101010B, it will reset the device after a delay time, t_{SRESET} . After power on the register will have a value of 01010101B.

RSTC7~RSTC0 Bits	Reset Function		
01010101B/10101010B	RES pin		
Any other value	Reset MCU		

Internal Reset Function Control

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RSTC Register

Bit	7	6	5	4	3	2	1	0
Name	RSTC7	RSTC6	RSTC5	RSTC4	RSTC3	RSTC2	RSTC1	RSTC0
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
POR	0	1	0	1	0	1	0	1

Bit 7~0 **RSTC7~RSTC0**: Reset function control

01010101/10101010: RES pin Other values: Reset MCU

If these bits are changed due to adverse environmental conditions, the microcontroller will be reset. The reset operation will be activated after a delay time, t_{SRESET} and the RSTF bit in the RSTFC register will be set to 1. All resets will reset this register to POR value except the WDT time out hardware warm reset.

RSTFC Register

Bit	7	6	5	4	3	2	1	0
Name	_	_	_	_	RSTF	_	_	WRF
R/W	_	_	_	_	R/W	_	_	R/W
POR	_	_	_	_	0	_	_	0

Bit 7~4 Unimplemented, read as "0"

Bit 3 RSTF: RSTC register software reset flag

0: Not occurred 1: Occurred

This bit is set to 1 by the RSTC control register software reset and cleared by the application program. Note that this bit can only be cleared to 0 by the application program.

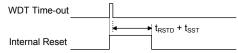
Bit 2~1 Unimplemented, read as "0"

Bit 0 WRF: WDTC register software reset flag

Described elsewhere

Watchdog Time-out Reset during Normal Operation

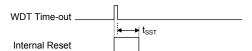
The Watchdog time-out Reset during normal operation is the same as the $\overline{\text{RES}}$ reset except that the Watchdog time-out flag TO will be set to "1".



WDT Time-out Reset during Normal Operation Timing Chart

Watchdog Time-out Reset during SLEEP or IDLE Mode

The Watchdog time-out Reset during SLEEP or IDLE Mode is a little different from other kinds of reset. Most of the conditions remain unchanged except that the Program Counter and the Stack Pointer will be cleared to zero and the TO flag will be set high. Refer to the A.C. Characteristics for t_{SST} details.



WDT Time-out Reset during SLEEP or IDLE Timing Chart

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Reset Initial Conditions

The different types of reset described affect the reset flags in different ways. These flags, known as PDF and TO are located in the status register and are controlled by various microcontroller operations, such as the SLEEP or IDLE Mode function or Watchdog Timer. The reset flags are shown in the table:

то	PDF	RESET Conditions				
0	0	Power-on reset				
u	u	RES reset during Normal operation				
1	u	WDT time-out reset during Normal operation				
1	1	WDT time-out reset during IDLE or SLEEP Mode operation				

Note: "u" stands for unchanged

The following table indicates the way in which the various components of the microcontroller are affected after a power-on reset occurs.

Item	Condition After RESET					
Program Counter	Reset to zero					
Interrupts	All interrupts will be disabled					
WDT, Time Base	Clear after reset, WDT begins counting					
Timer Module	Timer Module will be turned off					
Input/Output Ports	I/O ports will be setup as inputs					
Stack Pointer	Stack Pointer will point to the top of the stack					

The different kinds of resets all affect the internal registers of the microcontroller in different ways. To ensure reliable continuation of normal program execution after a reset occurs, it is important to know what condition the microcontroller is in after a particular reset occurs. The following table describes how each type of reset affects each of the microcontroller internal registers.

Register	Power On Reset	RES Reset (Normal Operation)	WDT Time-out (Normal Operation)	WDT Time-out (SLEEP/IDLE)
MP0	xxxx xxxx	xxxx xxxx	XXXX XXXX	uuuu uuuu
MP1	xxxx xxxx	xxxx xxxx	XXXX XXXX	uuuu uuuu
BP	000	000	000	u u u
ACC	xxxx xxxx	uuuu uuuu	uuuu uuuu	uuuu uuuu
PCL	0000 0000	0000 0000	0000 0000	0000 0000
TBLP	xxxx xxxx	uuuu uuuu	uuuu uuuu	uuuu uuuu
TBLH	xxxx xxxx	uuuu uuuu	uuuu uuuu	uuuu uuuu
TBHP	X X X	u u u	u u u	u u u
STATUS	00 xxxx	uu uuuu	1u uuuu	11 uuuu
RSTFC	0 0	u u	u u	u u
SCC	0001-	0001-	0001-	u u u u -
LVPUC	0	0	0	u
RSTC	0101 0101	0101 0101	0101 0101	uuuu uuuu
LVDC	00	00	00	uu
INTEG	0000	0000	0000	uuuu
WDTC	0101 0011	0101 0011	0101 0011	uuuu uuuu
INTC0	-000 0000	-000 0000	-000 0000	-uuu uuuu
INTC1	0000 0000	0000 0000	0000 0000	uuuu uuuu
INTC2	0000	0000	0000	uuuu
PSCR	00	0 0	0 0	u u
TB0C	0000	0000	0000	uuuu

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Register	Power On Reset	RES Reset	WDT Time-out	WDT Time-out
TD4O	0 000	(Normal Operation)	(Normal Operation)	(SLEEP/IDLE)
TB1C	0000	0000	0000	uuuu
PA	1111 1111	1111 1111	1111 1111	uuuu uuuu
PAC	1111 1111	1111 1111	1111 1111	uuuu uuuu
PAPU	0000 0000	0000 0000	0000 0000	uuuu uuuu
PAWU	0000 0000	0000 0000	0000 0000	uuuu uuuu
PB	1111 111-	1111 111-	1111 111-	uuuu uuu-
PBC	1111 111-	1111 111-	1111 111-	uuuu uuu-
PBPU	0000 000-	0000 000-	0000 000-	uuuu uuu-
PC	1111 1111	1111 1111	1111 1111	uuuu uuuu
PCC	1111 1111	1111 1111	1111 1111	uuuu uuuu
PCPU	0000 0000	0000 0000	0000 0000	uuuu uuuu
CTMC0	0000 0000	0000 0000	0000 0000	uuuu uuuu
CTMC1	0000 0000	0000 0000	0000 0000	uuuu uuuu
CTMDL	0000 0000	0000 0000	0000 0000	uuuu uuuu
CTMDH	00	0 0	0 0	u u
CTMAL	0000 0000	0000 0000	0000 0000	uuuu uuuu
СТМАН	00	0 0	0 0	u u
TMRAH	xxxx xxxx	xxxx xxxx	xxxx xxxx	uuuu uuuu
TMRAL	xxxx xxxx	XXXX XXXX	xxxx xxxx	uuuu uuuu
TMRC	-000 1	-000 1	-000 1	- u u u u
TMRBH	xxxx xxxx	xxxxxxx	xxxxxxx	uuuu uuuu
TMRBL	xxxx xxxx	xxxx xxxx	XXXX XXXX	uuuu uuuu
ADCR	000- 0000	000- 0000	000- 0000	uuu- uuuu
ELC	0	0	0	u
LCDC	0000	0000	0000	uuuu
EEA	-000 0000	-000 0000	-000 0000	uuuu uuuu
EED	0000 0000	0000 0000	0000 0000	uuuu uuuu
PAS0	00 00	00 00	00 00	uu uu
PAS1	0 0	0 0	0 0	u u
PBS1	0000 0000	0000 0000	0000 0000	uuuu uuuu
PCS0	0000 0000	0000 0000	0000 0000	uuuu uuuu
PCS1	0000 0000	0000 0000	0000 0000	uuuu uuuu
EEC	0000	0000	0000	uuuu

Note: "-" stands for unimplemented

"u" stands for unchanged

"x" stands for unknown



Input/Output Ports

Holtek microcontrollers offer considerable flexibility on their I/O ports. With the input or output designation of every pin fully under user program control, pull-high selections for all ports and wake-up selections on certain pins, the user is provided with an I/O structure to meet the needs of a wide range of application possibilities.

The device provides bidirectional input/output lines labeled with port names PA~PC. These I/O ports are mapped to the RAM Data Memory with specific addresses as shown in the Special Purpose Data Memory table. All of these I/O ports can be used for input and output operations. For input operation, these ports are non-latching, which means the inputs must be ready at the T2 rising edge of instruction "MOV A, [m]", where m denotes the port address. For output operation, all the data is latched and remains unchanged until the output latch is rewritten.

Register				В	it			
Name	7	6	5	4	3	2	1	0
PA	PA7	PA6	PA5	PA4	PA3	PA2	PA1	PA0
PAC	PAC7	PAC6	PAC5	PAC4	PAC3	PAC2	PAC1	PAC0
PAPU	PAPU7	PAPU6	PAPU5	PAPU4	PAPU3	PAPU2	PAPU1	PAPU0
PAWU	PAWU7	PAWU6	PAWU5	PAWU4	PAWU3	PAWU2	PAWU1	PAWU0
PB	PB7	PB6	PB5	PB4	PB3	PB2	PB1	_
PBC	PBC7	PBC6	PBC5	PBC4	PBC3	PBC2	PBC1	_
PBPU	PBPU7	PBPU6	PBPU5	PBPU4	PBPU3	PBPU2	PBPU1	_
PC	PC7	PC6	PC5	PC4	PC3	PC2	PC1	PC0
PCC	PCC7	PCC6	PCC5	PCC4	PCC3	PCC2	PCC1	PCC0
PCPU	PCPU7	PCPU6	PCPU5	PCPU4	PCPU3	PCPU2	PCPU1	PCPU0

I/O Logic Function Register List

Pull-high Resistors

Many product applications require pull-high resistors for their switch inputs usually requiring the use of an external resistor. To eliminate the need for these external resistors, all I/O pins, when configured as an input have the capability of being connected to an internal pull-high resistor. These pull-high resistors are selected using the relevant pull-high registers PAPU~PCPU together with the LVPUC register, and are implemented using weak PMOS transistors. The PxPU register is used to determine whether the pull-high function is enabled or not while the LVPUC register is used to select the pull-high resistor value for low voltage power supply applications.

Note that only when the I/O ports are configured as digital input or NMOS output, the internal pull-high functions can be enabled using the relevant pull-high control registers. Otherwise the pull-high resistors cannot be enabled.

PxPU Register

Bit	7	6	5	4	3	2	1	0
Name	PxPU7	PxPU6	PxPU5	PxPU4	PxPU3	PxPU2	PxPU1	PxPU0
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
POR	0	0	0	0	0	0	0	0

PxPUn: I/O Px.n Pin pull-high function control

0: Disable

The PxPUn bit is used to control the Px.n pin pull-high function. Here the "x" can be A, B or C. However, the actual available bits for each I/O Port may be different.

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LVPUC Register

Bit	7	6	5	4	3	2	1	0
Name	_	_	_	_	_	_	_	LVPU
R/W	_	_	_	_	_	_	_	R/W
POR	_	_	_	_	_	_	_	0

Bit 7~1 Unimplemented, read as "0"

LVPU: Pull-high resistor selection when low voltage power supply

0: All pin pull high resistor is $200K\Omega$ (typ.) @ 1.5V 1: All pin pull high resistor is $50K\Omega$ (typ.) @ 1.5V

This bit is used to select the pull-high resistor value for low voltage power supply applications. The LVPU bit is only available when the corresponding pin pull-high function is enabled by setting the relevant pull-high control bit high. This bit will have no effect when the pull-high function is disabled.

Port A Wake-up

Bit 0

The HALT instruction forces the microcontroller into the SLEEP or IDLE Mode which preserves power, a feature that is important for battery and other low-power applications. Various methods exist to wake-up the microcontroller, one of which is to change the logic condition on one of the Port A pins from high to low. This function is especially suitable for applications that can be woken up via external switches. Each pin on Port A can be selected individually to have this wake-up feature using the PAWU register.

Note that only when the Port A pins are configured as general purpose I/Os and the device is in the HALT status, the Port A wake-up functions can be enabled using the relevant bits in the PAWU register. In other conditions, the wake-up functions are disabled.

PAWU Register

Bit	7	6	5	4	3	2	1	0
Name	PAWU7	PAWU6	PAWU5	PAWU4	PAWU3	PAWU2	PAWU1	PAWU0
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
POR	0	0	0	0	0	0	0	0

Bit 7~0 PAWU7~PAWU0: Port A Pin Wake-up function Control

0: Disable 1: Enable

I/O Port Control Registers

Each I/O port has its own control register known as PAC~PCC, to control the input/output configuration. With this control register, each CMOS output or input can be reconfigured dynamically under software control. Each pin of the I/O ports is directly mapped to a bit in its associated port control register. For the I/O pin to function as an input, the corresponding bit of the control register must be written as a "1". This will then allow the logic state of the input pin to be directly read by instructions. When the corresponding bit of the control register is written as a "0", the I/O pin will be setup as a CMOS output. If the pin is currently setup as an output, instructions can still be used to read the output register. However, it should be noted that the program will in fact only read the status of the output data latch and not the actual logic status of the output pin.

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PxC Register

Bit	7	6	5	4	3	2	1	0
Name	PxC7	PxC6	PxC5	PxC4	PxC3	PxC2	PxC1	PxC0
R/W								
POR	1	1	1	1	1	1	1	1

PxCn: I/O Px.n Pin type selection

0: Output

1: Input

The PxCn bit is used to control the Px.n Pin type selection. Here the "x" can be A, B or C. However, the actual available bits for each I/O Port may be different.

Pin-shared Function

The flexibility of the microcontroller range is greatly enhanced by the use of pins that have more than one function. Limited numbers of pins can force serious design constraints on designers but by supplying pins with multi-functions, many of these difficulties can be overcome. For these pins, the desired function of the multi-function I/O pins is selected by a series of registers via the application program control.

Pin-shared Function Selection Registers

The limited number of supplied pins in a package can impose restrictions on the amount of functions a certain device can contain. However by allowing the same pins to share several different functions and providing a means of function selection, a wide range of different functions can be incorporated into even relatively small package sizes. The device includes the Port "x" Output Function Selection registers, labeled as PxS0 and PxS1, which can select the desired functions of the multi-function pin-shared pins.

The most important point to note is to make sure that the desired pin-shared function is properly selected and also deselected. To select the desired pin-shared function, the pin-shared function should first be correctly selected using the corresponding pin-shared control register. After that the corresponding peripheral functional setting should be configured and then the peripheral function can be enabled. To correctly deselect the pin-shared function, the peripheral function should first be disabled and then the corresponding pin-shared function control register can be modified to select other pin-shared functions.

Register	Bit							
Name	7	6	5	4	3	2	1	0
PAS0	PAS07	PAS06	_	_	PAS03	PAS02	_	_
PAS1	_	_	_	_	_	_	PAS11	PAS10
PBS1	PBS17	PBS16	PBS15	PBS14	PBS13	PBS12	PBS11	PBS10
PCS0	PCS07	PCS06	PCS05	PCS04	PCS03	PCS02	PCS01	PCS00
PCS1	PCS17	PCS16	PCS15	PCS14	PCS13	PCS12	PCS11	PCS10

Pin-shared Function Selection Register List

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PAS0 Register

Bit	7	6	5	4	3	2	1	0
Name	PAS07	PAS06	_	_	PAS03	PAS02	_	_
R/W	R/W	R/W	_	_	R/W	R/W	_	_
POR	0	0	_	_	0	0	_	_

Bit 7~6 **PAS07~PAS06**: PA3 pin-shared function selection

00: PA3

01: PA3

10: PA3 11: CTP

Bit 5~4 Unimplemented, read as "0"

Dit 5-4 Chimpiemented, read as 0

Bit3~2 PAS03~PAS02: PA1 pin-shared function selection

00: PA1

01: PA1

10: PA1

11: EL

Bit 1~0 Unimplemented, read as "0"

• PAS1 Register

Bit	7	6	5	4	3	2	1	0
Name	_	_	_	_	_	_	PAS11	PAS10
R/W	_	_	_	_	_	_	R/W	R/W
POR	_	_	_	_	_	_	0	0

Bit 7~2 Unimplemented, read as "0"

Bit 1~0 PAS11~PAS10: PA4 pin-shared function selection

00: PA4

01: PA4

10: PA4

11: CTPB

• PBS1 Register

Bit	7	6	5	4	3	2	1	0
Name	PBS17	PBS16	PBS15	PBS14	PBS13	PBS12	PBS11	PBS10
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
POR	0	0	0	0	0	0	0	0

Bit 7~6 **PBS17~PBS16**: PB7 pin-shared function selection

00: PB7

01: PB7

10: PB7

11: SEG11

Bit 5~4 **PBS15~PBS14**: PB6 pin-shared function selection

00: PB6

01: PB6

10: PB6 11: SEG10

Bit 3~2 **PBS13~PBS12**: PB5 pin-shared function selection

00: PB5

01: PB5

10: PB5

11: SEG9

Bit 1~0 **PBS11~PBS10**: PB4 pin-shared function selection

00: PB4

01: PB4

10: PB4

11: SEG8

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PCS0 Register

Bit	7	6	5	4	3	2	1	0
Name	PCS07	PCS06	PCS05	PCS04	PCS03	PCS02	PCS01	PCS00
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
POR	0	0	0	0	0	0	0	0

Bit 7~6 PCS07~PCS06: PC3 pin-shared function selection

00: PC3

01: PC3

10: PC3

11: SEG3

Bit 5~4 PCS05~PCS04: PC2 pin-shared function selection

00: PC2

01: PC2

10: PC2

11: SEG2

Bit 3~2 PCS03~PCS02: PC1 pin-shared function selection

00: PC1

01: PC1

10: PC1

11: SEG1

Bit 1~0 PCS01~PCS00: PC0 pin-shared function selection

00: PC0

01: PC0

10: PC0

11: SEG0

• PCS1 Register

Bit	7	6	5	4	3	2	1	0
Name	PCS17	PCS16	PCS15	PCS14	PCS13	PCS12	PCS11	PCS10
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
POR	0	0	0	0	0	0	0	0

Bit 7~6 **PCS17~PCS16**: PC7 pin-shared function selection

00: PC7

01: PC7

10: PC7

11: SEG7

Bit 5~4 PCS15~PCS14: PC6 pin-shared function selection

00: PC6

01: PC6

10: PC6

11: SEG6

Bit 3~2 PCS13~PCS12: PC5 pin-shared function selection

00: PC5

01: PC5

10: PC5

11: SEG5

Bit 1~0 PCS11~PCS10: PC4 pin-shared function selection

00: PC4

01: PC4

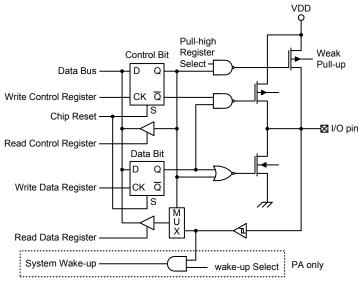
10: PC4

11: SEG4



I/O Pin Structures

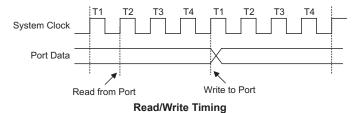
The accompanying diagrams illustrate the internal structures of some generic I/O pin types. As the exact logical construction of the I/O pin will differ from these drawings, they are supplied as a guide only to assist with the functional understanding of the I/O pins. The wide range of pin-shared structures does not permit all types to be shown.



Logic Function Input/Output Structure

Programming Considerations

Within the user program, one of the first things to consider is port initialisation. After a reset, all of the I/O data and port control registers will be set high. This means that all I/O pins will default to an input state, the level of which depends on the other connected circuitry and whether pull-high selections have been chosen. If the port control registers, PAC~PCC, are then programmed to setup some pins as outputs, these output pins will have an initial high output value unless the associated port data registers, PA~PC, are first programmed. Selecting which pins are inputs and which are outputs can be achieved byte-wide by loading the correct values into the appropriate port control register or by programming individual bits in the port control register using the "SET [m].i" and "CLR [m].i" instructions. Note that when using these bit control instructions, a read-modify-write operation takes place. The microcontroller must first read in the data on the entire port, modify it to the required new bit values and then rewrite this data back to the output ports.



Port A has the additional capability of providing wake-up functions. When the device is in the SLEEP or IDLE Mode, various methods are available to wake the device up. One of these is a high to low transition of any of the Port A pins. Single or multiple pins on Port A can be setup to have this

function.

Timer Modules - TM

One of the most fundamental functions in any microcontroller device is the ability to control and measure time. To implement time related functions the device includes one Timer Module, abbreviated to the name TM. The TM is a multi-purpose timing unit and serves to provide operations such as Timer/Counter, Compare Match Output as well as being the functional unit for the generation of PWM signals. The TM has two individual interrupts. The addition of input and output pins for the TM ensures that users are provided with timing units with a wide and flexible range of features.

The general features of the Compact type TM are described here with more detailed information provided in the Compact type TM section.

Introduction

The device contains one Compact type TM having a reference name of CTM. The common features to the Compact TM will be described in this section and the detailed operation will be described in the corresponding section. The main features of the CTM are summarised in the accompanying table.

Function	СТМ
Timer/Counter	√
Compare Match Output	√
PWM Channel	1
PWM Alignment	Edge
PWM Adjustment Period & Duty	Duty or Period

CTM Function Summary

TM Operation

The Compact type TM offers a diverse range of functions, from simple timing operations to PWM signal generation. The key to understanding how the TM operates is to see it in terms of a free running counter whose value is then compared with the value of pre-programmed internal comparators. When the free running counter has the same value as the pre-programmed comparator, known as a compare match situation, a TM interrupt signal will be generated which can clear the counter and perhaps also change the condition of the TM output pin. The internal TM counter is driven by a user selectable clock source, which can be an internal clock or an external pin.

TM Clock Source

The clock source which drives the main counter in the TM can originate from various sources. The selection of the required clock source is implemented using the CTCK2~CTCK0 bits in the CTM control register. The clock source can be a ratio of the system clock fSYS or the internal high clock fH, the fSUB clock source or the external CTCK pin. The CTCK pin clock source is used to allow an external signal to drive the TM as an external clock source or for event counting.

TM Interrupts

The Compact type TM has two internal interrupts, one for each of the internal comparator A or comparator P, which generate a TM interrupt when a compare match condition occurs. When a TM interrupt is generated it can be used to clear the counter and also to change the state of the TM output pin.

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TM External Pins

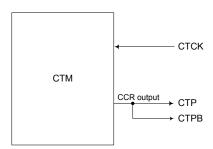
The Compact TM has one input pin, with the label CTCK. The CTCK input pin is essentially a clock source for the CTM and is selected using the CTCK2~CTCK0 bits in the CTMC0 register. This external TM input pin allows an external clock source to drive the internal TM. The CTCK input pin can be chosen to have either a rising or falling active edge.

The Compact TM also has two output pins, CTP and CTPB. The CTPB is the inverted signal of the CTP output. When the TM is in the Compare Match Output Mode, these pins can be controlled by the TM to switch to a high or low level or to toggle when a compare match situation occurs. The external CTP and CTPB output pins are also the pins where the TM generates the PWM output waveform.

As the CTM input and output pins are pin-shared with other functions, the TM input or output function must first be setup using relevant pin-shared function selection register. The details of the pin-shared function selection are described in the pin-shared function section.

	CTM External Pins							
Input Output								
	CTCK	СТР, СТРВ						

CTM External Pins



CTM Function Pin Block Diagram

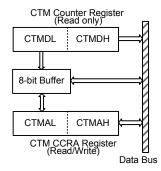
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Programming Considerations

The TM Counter Registers, the Capture/Compare CCRA register, being 10-bit, has a low and high byte structure. The high byte can be directly accessed, but as the low byte can only be accessed via an internal 8-bit buffer, reading or writing to this register pair must be carried out in a specific way. The important point to note is that data transfer to and from the 8-bit buffer and its related low byte only takes place when a write or read operation to its corresponding high byte is executed.

As the CCRA register is implemented in the way shown in the following diagram and accessing these registers is carried out in a specific way described above, it is recommended to use the "MOV" instruction to access the CCRA low byte register, named CTMAL, using the following access procedures. Accessing the CCRA low byte register without following these access procedures will result in unpredictable values.



The following steps show the read and write procedures:

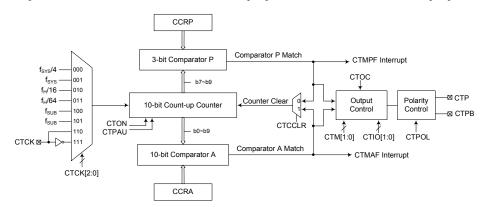
- · Writing Data to CCRA
 - Step 1. Write data to Low Byte CTMAL
 - Note that here data is only written to the 8-bit buffer.
 - Step 2. Write data to High Byte CTMAH
 - Here data is written directly to the high byte register and simultaneously data is latched from the 8-bit buffer to the Low Byte registers.
- Reading Data from the Counter and CCRA Registers
 - Step 1. Read data from the High Byte CTMDH or CTMAH
 - Here data is read directly from the High Byte register and simultaneously data is latched from the Low Byte register into the 8-bit buffer.
 - Step 2. Read data from the Low Byte CTMDL or CTMAL
 - This step reads data from the 8-bit buffer.

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Compact Type TM - CTM

Although the simplest form of the TM types, the Compact TM type still contains three operating modes, which are Compare Match Output, Timer/Event Counter and PWM Output modes. The Compact TM cso be controlled with an external input pin and can drive two external output pins



Note: As the CTM external pins are pin-shared with other function, so before using the CTM function, make sure the corresponding pin-shared function registert be set properly.

Compact Type TM Block Diagram

Compact Type TM Operation

At its core is a 10-bit count-up counter which is driven by a user selectable internal or external clock source. There are also two internal comparators with the names, Comparator A and Comparator P. These comparators will compare the value in the counter with CCRP and CCRA registers. The CCRP is 3-bit wide whose value is compared with the highest three bits in the counter while the CCRA is 10-bit wide and therefore compares with all counter bits.

The only way of changing the value of the 10-bit counter using the application program, is to clear the counter by changing the CTON bit from low to high. The counter will also be cleared automatically by a counter overflow or a compare match with one of its associated comparators. When these conditions occur, a CTM interrupt signal will also usually be generated. The Compact Type TM can operate in a number of different operational modes, can be driven by different clock sources including an input pin and can also control two output pins. All operating setup conditions are selected using relevant internal registers.

Compact Type TM Register Description

Overall operation of the Compact Type TM is controlled using a series of registers. A read only register pair exists to store the internal counter 10-bit value, while a read/write register pair exists to store the internal 10-bit CCRA value. The remaining two registers are control registers which setup the different operating and control modes as well as the three CCRP bits.

Register		Bit										
Name	7	6	5	4	3	2	1	0				
CTMC0	CTPAU	CTCK2	CTCK1	CTCK0	CTON	CTRP2	CTRP1	CTRP0				
CTMC1	CTM1	CTM0	CTIO1	CTIO0	CTOC	CTPOL	CTDPX	CTCCLR				
CTMDL	D7	D6	D5	D4	D3	D2	D1	D0				
CTMDH	_	_	_	_	_	_	D9	D8				
CTMAL	D7	D6	D5	D4	D3	D2	D1	D0				
СТМАН	_	_	_	_	_	_	D9	D8				

10-bit Compact TM Register List

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· CTMC0 Register

HOLTEK

Bit	7	6	5	4	3	2	1	0
Name	CTPAU	CTCK2	CTCK1	CTCK0	CTON	CTRP2	CTRP1	CTRP0
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
POR	0	0	0	0	0	0	0	0

Bit 7 CTPAU: CTM Counter Pause Control

0: Run 1: Pause

The counter can be paused by setting this bit high. Clearing the bit to zero restores normal counter operation. When in a Pause condition the CTM will remain powered up and continue to consume power. The counter will retain its residual value when this bit changes from low to high and resume counting from this value when the bit changes to a low value again.

Bit 6~4 CTCK2~CTCK0: Select CTM Counter clock

000: f_{SYS}/4 001: f_{SYS} 010: f_H/16 011: f_H/64 100: f_{SUB} 101: f_{SUB}

110: CTCK rising edge clock 111: CTCK falling edge clock

These three bits are used to select the clock source for the CTM. The external pin clock source can be chosen to be active on the rising or falling edge. The clock source f_{SYS} is the system clock, while f_H and f_{SUB} are other internal clocks, the details of which can be found in the Operating Modes and System Clocks section.

Bit 3 CTON: CTM Counter On/Off Control

0: Off 1: On

This bit controls the overall on/off function of the CTM. Setting the bit high enables the counter to run; clearing the bit disables the CTM. Clearing this bit to zero will stop the counter from counting and turn off the CTM which will reduce its power consumption. When the bit changes state from low to high the internal counter value will be reset to zero, however when the bit changes from high to low, the internal counter will retain its residual value until the bit returns high again.

If the CTM is in the Compare Match Output Mode or the PWM Output Mode then the CTM output pin will be reset to its initial condition, as specified by the CTOC bit, when the CTON bit changes from low to high.

Bit 2~0 CTRP2~CTRP0: CTM CCRP 3-bit register, compared with the CTM Counter bit 9~bit 7 Comparator P Match Period

000: 1024 CTM clocks 001: 128 CTM clocks 010: 256 CTM clocks 011: 384 CTM clocks 100: 512 CTM clocks 101: 640 CTM clocks 110: 768 CTM clocks 111: 896 CTM clocks

These three bits are used to setup the value on the internal CCRP 3-bit register, which are then compared with the internal counter's highest three bits. The result of this comparison can be selected to clear the internal counter if the CTCCLR bit is set to zero. Setting the CTCCLR bit to zero ensures that a compare match with the CCRP values will reset the internal counter. As the CCRP bits are only compared with the highest three counter bits, the compare values exist in 128 clock cycle multiples. Clearing all three bits to zero is in effect allowing the counter to overflow at its maximum value.

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CTMC1 Register

Bit	7	6	5	4	3	2	1	0
Name	CTM1	CTM0	CTIO1	CTIO0	CTOC	CTPOL	CTDPX	CTCCLR
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
POR	0	0	0	0	0	0	0	0

Bit 7~6 CTM1~CTM0: Select CTM Operating Mode

00: Compare Match Output Mode

01: Undefined

10: PWM Output Mode11: Timer/Counter Mode

These bits setup the required operating mode for the CTM. To ensure reliable operation the CTM should be switched off before any changes are made to the CTM1 and CTM0 bits. In the Timer/Counter Mode, the CTM output pin state is undefined.

Bit 5~4 CTIO1~CTIO0: Select CTP output function

Compare Match Output Mode

00: No change

01: Output low

10: Output high

11: Toggle output

PWM Output Mode

00: PWM Output inactive state

01: PWM Output active state

10: PWM Output

11: Undefined

Timer/Counter Mode

Unused

These two bits are used to determine how the CTM output pin changes state when a certain condition is reached. The function that these bits select depends upon in which mode the CTM is running.

In the Compare Match Output Mode, the CTIO1 and CTIO0 bits determine how the CTM output pin changes state when a compare match occurs from the Comparator A. The CTM output pin can be setup to switch high, switch low or to toggle its present state when a compare match occurs from the Comparator A. When the bits are both zero, then no change will take place on the output. The initial value of the CTM output pin should be setup using the CTOC bit in the CTMC1 register. Note that the output level requested by the CTIO1 and CTIO0 bits must be different from the initial value setup using the CTOC bit otherwise no change will occur on the CTM output pin when a compare match occurs. After the CTM output pin changes state it can be reset to its initial level by changing the level of the CTON bit from low to high.

In the PWM Output Mode, the CTIO1 and CTIO0 bits determine how the CTM output pin changes state when a certain compare match condition occurs. The PWM output function is modified by changing these two bits. It is necessary to only change the values of the CTIO1 and CTIO0 bits only after the CTM has been switched off. Unpredictable PWM outputs will occur if the CTIO1 and CTIO0 bits are changed when The CTM is running.

Bit 3 CTOC: CTP Output control bit

Compare Match Output Mode

0: Initial low

1: Initial high

PWM Output Mode

0: Active low

1: Active high

This is the output control bit for the CTP output pin. Its operation depends upon whether CTM is being used in the Compare Match Output Mode or in the PWM

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Output Mode. It has no effect if the CTM is in the Timer/Counter Mode. In the Compare Match Output Mode it determines the logic level of the CTM output pin before a compare match occurs. In the PWM Output Mode it determines if the PWM signal is active high or active low.

Bit 2 CTPOL: CTP Output polarity Control

0: Non-invert 1: Invert

This bit controls the polarity of the CTP output pin. When the bit is set high the CTP output pin will be inverted and not inverted when the bit is zero. It has no effect if the CTM is in the Timer/Counter Mode.

Bit 1 CTDPX: CTM PWM period/duty Control

0: CCRP – period, CCRA – duty 1: CCRP – duty; CCRA – period

This bit determines which of the CCRA and CCRP registers are used for period and duty control of the PWM waveform.

Bit 0 CTCCLR: Select CTM Counter clear condition

0: CTM Comparatror P match1: CTM Comparatror A match

This bit is used to select the method which clears the counter. Remember that the Compact TM contains two comparators, Comparator A and Comparator P, either of which can be selected to clear the internal counter. With the CTCCLR bit set high, the counter will be cleared when a compare match occurs from the Comparator A. When the bit is low, the counter will be cleared when a compare match occurs from the Comparator P or with a counter overflow. A counter overflow clearing method can only be implemented if the CCRP bits are all cleared to zero. The CTCCLR bit is not used in the PWM Output Mode.

CTMDL Register

Bit	7	6	5	4	3	2	1	0
Name	D7	D6	D5	D4	D3	D2	D1	D0
R/W	R	R	R	R	R	R	R	R
POR	0	0	0	0	0	0	0	0

Bit 7~0 **D7~D0**: CTM Counter Low Byte Register bit 7~bit 0 CTM 10-bit Counter bit 7~bit 0

CTMDH Register

Bit	7	6	5	4	3	2	1	0
Name	_	_	_	_	_	_	D9	D8
R/W	_	_	_	_	_	_	R	R
POR	_	_	_	_	_	_	0	0

Bit 7~2 Unimplemented, read as "0"

Bit 1~0 **D9~D8**: CTM Counter High Byte Register bit 1~bit 0

CTM 10-bit Counter bit 9~bit 8

CTMAL Register

Bit	7	6	5	4	3	2	1	0
Name	D7	D6	D5	D4	D3	D2	D1	D0
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
POR	0	0	0	0	0	0	0	0

Bit 7~0 **D7~D0**: CTM CCRA Low Byte Register bit 7~bit 0 CTM 10-bit CCRA bit 7~bit 0

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CTMAH Register

Bit	7	6	5	4	3	2	1	0
Name	_	_	_	_	_	_	D9	D8
R/W	_	_	_	_	_	_	R/W	R/W
POR	_	_	_	_	_	_	0	0

Bit 7~2 Unimplemented, read as "0"

Bit 1~0 **D9~D8**: CTM CCRA High Byte Register bit 1~bit 0

CTM 10-bit CCRA bit 9~bit 8

Compact Type TM Operating Modes

The Compact Type TM can operate in one of three operating modes, Compare Match Output Mode, PWM Output Mode or Timer/Counter Mode. The operating mode is selected using the CTM1 and CTM0 bits in the CTMC1 register.

Compare Match Output Mode

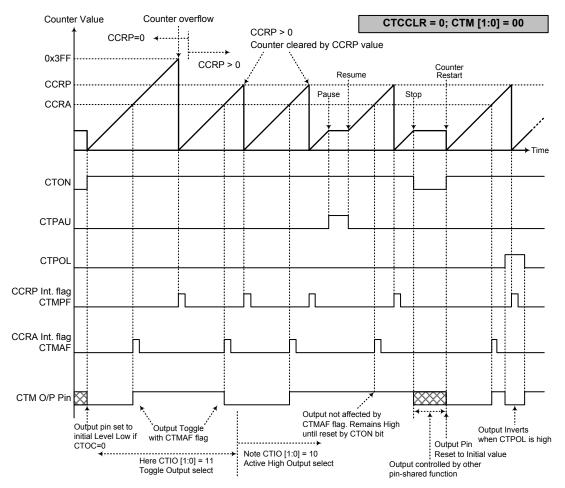
To select this mode, bits CTM1 and CTM0 in the CTMC1 register, should be set to 00 respectively. In this mode once the counter is enabled and running it can be cleared by three methods. These are a counter overflow, a compare match from Comparator A and a compare match from Comparator P. When the CTCCLR bit is low, there are two ways in which the counter can be cleared. One is when a compare match occurs from Comparator P, the other is when the CCRP bits are all zero which allows the counter to overflow. Here both CTMAF and CTMPF interrupt request flags for the Comparator A and Comparator P respectively, will both be generated.

If the CTCCLR bit in the CTMC1 register is high then the counter will be cleared when a compare match occurs from Comparator A. However, here only the CTMAF interrupt request flag will be generated even if the value of the CCRP bits is less than that of the CCRA registers. Therefore when CTCCLR is high no CTMPF interrupt request flag will be generated. If the CCRA bits are all zero, the counter will overflow when it reaches its maximum 10-bit, 3FF Hex, value, however here the CTMAF interrupt request flag will not be generated.

As the name of the mode suggests, after a comparison is made, the CTM output pin will change state. The CTM output pin condition however only changes state whenan CTMAF interrupt request flag is generated after a compare match occurs from Comparator A. The CTMPF interrupt request flag, generated from a compare match occurs from Comparator P, will have no effect on the CTM output pin. The way in which the CTM output pin changes state are determined by the condition of the CTIO1 and CTIO0 bits in the CTMC1 register. The CTM output pin can be selected using the CTIO1 and CTIO0 bits to go high, to go low or to toggle from its present condition when a compare match occurs from Comparator A. The initial condition of the CTM output pin, which is setup after the CTON bit changes from low to high, is setup using the CTOC bit. Note that if the CTIO1 and CTIO0 bits are zero then no pin change will take place.

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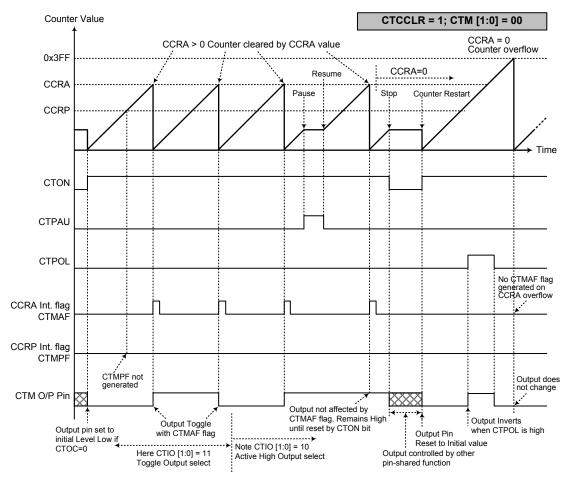
Compare Match Output Mode - CTCCLR=0

Note: 1. With CTCCLR = 0, a Comparator P match will clear the counter

- 2. The CTM output pin is controlled only by the CTMAF flag
- 3. The output pin reset to initial state by a CTON bit rising edge

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Compare Match Output Mode - CTCCLR=1

Note: 1. With CTCCLR = 1, a Comparator A match will clear the counter

- 2. The CTM output pin is controlled only by the CTMAF flag
- 3. The output pin reset to initial state by a CTON bit rising edge
- 4. The CTMPF flags is not generated when CTCCLR = 1

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Timer/Counter Mode

To select this mode, bits CTM1 and CTM0 in the CTMC1 register should be set to 11 respectively. The Timer/Counter Mode operates in an identical way to the Compare Match Output Mode generating the same interrupt flags. The exception is that in the Timer/Counter Mode the CTM output pin is not used. Therefore the above description and Timing Diagrams for the Compare Match Output Mode can be used to understand its function. As the CTM output pin is not used in this mode, the pin can be used as a normal I/O pin or other pin-shared functions.

PWM Output Mode

To select this mode, bits CTM1 and CTM0 in the CTMC1 register should be set to 10 respectively. The PWM function within the CTM is useful for applications which require functions such as motor control, heating control, illumination control etc. By providing a signal of fixed frequency but of varying duty cycle on the CTM output pin, a square wave AC waveform can be generated with varying equivalent DC RMS values.

As both the period and duty cycle of the PWM waveform can be controlled, the choice of generated waveform is extremely flexible. In the PWM Output Mode, the CTCCLR bit has no effect on the PWM operation. Both of the CCRA and CCRP registers are used to generate the PWM waveform, one register is used to clear the internal counter and thus control the PWM waveform frequency, while the other one is used to control the duty cycle. Which register is used to control either frequency or duty cycle is determined using the CTDPX bit in the CTMC1 register. The PWM waveform frequency and duty cycle can therefore be controlled by the values in the CCRA and CCRP registers.

An interrupt flag, one for each of the CCRA and CCRP, will be generated when a compare match occurs from either Comparator A or Comparator P. The CTOC bit in the CTMC1 register is used to select the required polarity of the PWM waveform while the two CTIO1 and CTIO0 bits are used to enable the PWM output or to force the CTM output pin to a fixed high or low level. The CTPOL bit is used to reverse the polarity of the PWM output waveform.

• 10-bit CTM, PWM Output Mode, Edge-aligned Mode, CTDPX=0

CCRP	001b	010b	011b	100b	101b	110b	111b	000b	
Period	128	256	384	512	640	768	896	1024	
Duty	CCRA								

If $f_{SYS} = 32$ kHz, CTM clock source is $f_{SYS}/4$, CCRP = 100b, CCRA = 128,

The CTM PWM output frequency = $(f_{SYS}/4) / 512 = f_{SYS}/2048 = 16$ Hz, duty = 128/512 = 25%.

If the Duty value defined by the CCRA register is equal to or greater than the Period value, then the PWM output duty is 100%.

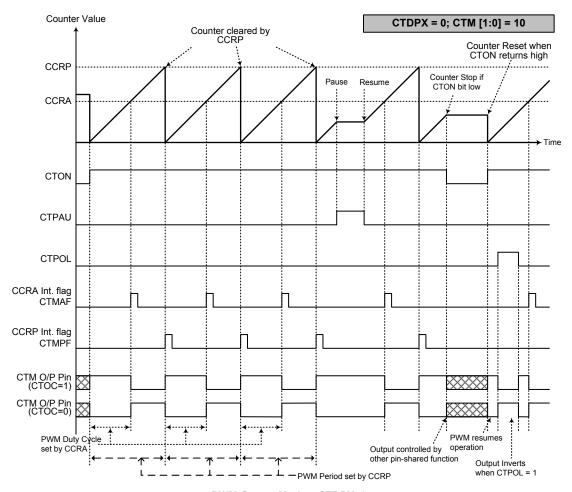
• 10-bit CTM, PWM Output Mode, Edge-aligned Mode, CTDPX=1

CCRP	001b	010b	011b	100b	101b	110b	111b	000b			
Period		CCRA									
Duty	128	256	384	512	640	768	896	1024			

The PWM output period is determined by the CCRA register value together with the CTM clock while the PWM duty cycle is defined by the CCRP register value.

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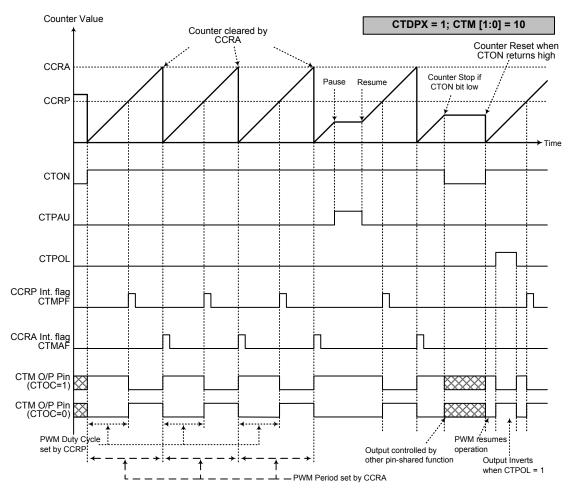


PWM Output Mode - CTDPX=0

Note: 1. Here CTDPX = 0 – Counter cleared by CCRP

- 2. A counter clear sets the PWM Period
- 3. The internal PWM function continues running even when CTIO[1:0] = 00 or 01
- 4. The CTCCLR bit has no influence on PWM operation





PWM Output Mode - CTDPX=1

Note: 1. Here CTDPX = 1 - Counter cleared by CCRA

- 2. A counter clear sets the PWM Period
- 3. The internal PWM function continues even when CTIO[1:0] = 00 or 01
- 4. The CTCCLR bit has no influence on PWM operation

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R to F Converter

The device provides a dual-channel R to F converter which contains two R to F oscillation circuits, two 16-bit timers of Timer A and Timer B. By configuring the related mode selection bit the R to F converter can operate in two modes which are the 16-bit Timer/Event Counter mode and the R to F Converter mode. The R to F converter mode is used for resistance to frequency conversion while the 16-bit Timer/Event Counter mode is used for external event counting, time interval measurement and other time related functions.

R to F Converter Register Description

There are six registers related to the R to F converter, i.e., TMRAH, TMRAL, TMRC, TMRBH, TMRBL and ADCR. The TMRAH & TMRAL register and the TMRBH & TMRBL register pair can be used as counters or pre-load registers determined by which mode being implemented. The ADCR register is used to select the R to F converter mode or the Timer/Event Counter mode, the LIRC2 oscillator control, the converter mode control and timer clock selection. The TMRC register control the timer operations.

Register					Bit			
Name	7	6	5	4	3	2	1	0
TMRAL	D7	D6	D5	D4	D3	D2	D1	D0
TMRAH	D15	D14	D13	D12	D11	D10	D9	D8
TMRBL	D7	D6	D5	D4	D3	D2	D1	D0
TMRBH	D15	D14	D13	D12	D11	D10	D9	D8
ADCR	CHSEL	TMBSEL	LIRC2ON	_	_	RSEL	AD_TMB	OVB_OVAB
TMRC	_	TM1	TM0	TON	TE	_	_	_

R to F Converter Register List

TMRAL Register

Bit	7	6	5	4	3	2	1	0
Name	D7	D6	D5	D4	D3	D2	D1	D0
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
POR	х	х	х	х	х	х	х	х

Bit 7~0 **D7~D0**: Timer A pre-load register low byte

• TMRAH Register

Bit	7	6	5	4	3	2	1	0
Name	D15	D14	D13	D12	D11	D10	D9	D8
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
POR	Х	Х	Х	Х	Х	Х	Х	Х

Bit 7~0 **D15~D8**: Timer A pre-load register high byte

TMRBL Register

Bit	7	6	5	4	3	2	1	0
Name	D7	D6	D5	D4	D3	D2	D1	D0
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
POR	х	х	х	х	Х	х	Х	х

Bit 7~0 **D7~D0**: Timer B pre-load register low byte

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TMRBH Register

Bit	7	6	5	4	3	2	1	0
Name	D15	D14	D13	D12	D11	D10	D9	D8
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
POR	х	Х	Х	Х	х	х	Х	Х

Bit 7~0 D15~D8: Timer B pre-load register high byte

ADCR Register

	Bit	7	6	5	4	3	2	1	0
	Name	CHSEL	TMBSEL	LIRC2ON	_	_	RSEL	AD_TMB	OVB_OVAB
	R/W	R/W	R/W	R/W	_	_	R/W	R/W	R/W
ĺ	POR	0	0	0	_	_	0	0	0

Bit 7 CHSEL: Select the input channel

0: From R to F oscillator 0 output

1: From R to F oscillator 1 output

Bit 6 TMBSEL: Timer B clock source selection in R to F converter mode

0: LIRC2 oscillator 1: R to F oscillator output

Note that this bit is only available when the R to F Converter mode is enabled (AD TMB=1).

LIRC2ON: LIRC2 oscillator enable control Bit 5

0: Disable 1: Enable

Bit 4~3 Unimplemented, read as "0"

Bit 2 RSEL: R to F Converter operating mode selection

> 0: RREF~CREF oscillation (reference resistor and reference capacitor) 1: RSEN~CREF oscillation (resistor sensor and reference capacitor)

The RSEL bit decides which resistor and capacitor compose an oscillation circuit and input to TMRBH and TMRBL in R to F converter mode.

AD_TMB: R to F Converter or 16-bit Timer/Event counter mode selection Bit 1

0: 16-bit Timer/Event counter is enabled

1: R to F Converter is enabled

Bit 0 OVB OVAB: Interrupt source select in R to F converter mode

0: Timer A overflow 1: Timer B overflow

In the R to F converter mode, this bit is used to define the timer/event counter interrupt which comes from Timer A or Timer B overflow. In timer/event counter mode, this bit is not available.

· TMRC Register

Bit	7	6	5	4	3	2	1	0
Name	_	TM1	TM0	TON	TE	_	_	_
R/W	_	R/W	R/W	R/W	R/W	_	_	_
POR	_	0	0	0	1	_	_	_

Bit 7 Unimplemented, read as "0"

Bit 6~5 TM1~TM0: Timer operation mode selection

00: Unused

01: Event counter mode (Timer A from external clock: RCIN0/RCIN1)

10: Timer mode

11: Pulse width measurement mode

Note if the R to F converter mode is selected (AD TMB=1), it is recommended that the TM[1:0] bits are set as 10 to select the system clock as the timer A clock source.

Bit 4 TON: Timer/event counter counting enable

0: Disable 1: Enable

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Bit 3 TE: Timer/event counter active edge selection

In Event Counter Mode
0: Count on rising edge

1: Count on falling edge
In Pulse width measurement Mode

0: Start counting on falling edge, stop on rising edge 1: Start counting on rising edge, stop on falling edge

Bit $2 \sim 0$ Unimplemented, read as "0"

Timer/Event Counter

The TMRAL, TMRAH, TMRBL and TMRBH form one 16-bit timer/event counter when AD_TMB bit is "0". The TMRBL and TMRBH are timer/event counter preload registers for lower-order byte and higher-order byte respectively.

The timer/event counter clock source comes from system clock (f_{SYS}) or external source. The external clock input allows the user to count external events, count external RC oscillation clock, measure time intervals or pulse widths, or generate an accurate time base.

The TMRC is the timer/event counter control register, which defines the timer/event counter options. The timer/event counter control register defines the operating mode, counting enable or disable and active edge. Writing to timer B location puts the starting value in the timer/event counter preload register, while reading timer A yields the contents of the timer/event counter. Timer B is the timer/event counter preload register.

Write/Read Procedures

Writing to TMRBL only writes the data into a low byte buffer, and writing to TMRBH will write the data and the contents of the low byte buffer into the time/event counter preload register (16-bit) simultaneously. The timer/event counter preload register is changed by writing to TMRBH operations and writing to TMRBL will keep the timer/event counter preload register unchanged.

Reading TMRAH will also latch the TMRAL into the low byte buffer to avoid false timing problem. Reading TMRAL returns the contents of the low byte buffer. In other words, the low byte of the timer/event counter can not be read directly. It must read the TMRAH first to make the low byte contents of timer/event counter be latched into the buffer.

In the case of timer/event counter off condition, writing data to the timer/event counter preload register also reloads that data to the timer/event counter. But if the timer/event counter turns on, data written to the timer/event counter preload register is kept only in the timer/event counter preload register. The timer/event counter will still operate until overflow occurs.

When the timer/event counter (reading TMRAH) is read, the clock will be blocked to avoid errors. As this may results in a counting error, this must be taken into consideration.

It is strongly recommended to load first the desired value into TMRBL, TMRBH, TMRAL, and TMRAH registers then turn on the related timer/event counter for proper operation. Because the initial value of TMRBL, TMRBH, TMRAL and TMRAH are unknown.

Timer/Event Counter Operation Mode

The TM0 and TM1 bits define the operation mode. The event count mode is used to count external events, which means that the clock source comes from an external pin. The timer mode functions as a normal timer with the clock source coming from the internal clock (f_{SYS}). Finally, the pulse width measurement mode can be used to count the high or low level duration of the external signal that input from RCIN0 or RCIN1 pin.

In the event count mode or internal timer mode, once the timer/event counter starts counting, it will count from the current contents in the timer/event counter (TMRAH and TMRAL) to FFFFH. Once

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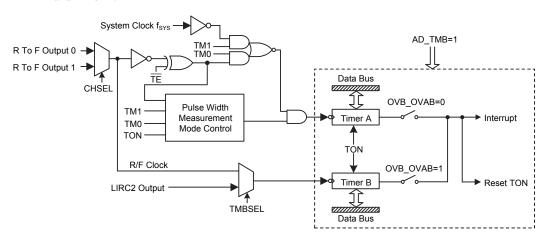
overflow occurs, the counter is reloaded from the timer/event counter preload register (TMRBH and TMRBL) and at the same time generates the corresponding interrupt request flag.

In the pulse width measurement mode with the TON and TE bits equal to one, once the RCINn has received a transient from low to high (or high to low if the TE bit is 0) it will start counting until the external clock returns to the original level and resets the TON. The measured result will remain in the timer/event counter even if the activated transient occurs again. In other words, only one cycle measurement can be done. Until setting the TON, the cycle measurement will function again as long as it receives further transient pulse. Note that in this operation mode, the timer/event counter starts counting not according to the logic level but according to the transient edges. In the case of counter overflow, the counter is reloaded from the timer/event counter preload register and issues interrupt request just like the other two modes.

To enable the counting operation, the timer on bit (TON) should be set to 1. In the pulse width measurement mode, the TON will automatically be cleared after the measurement cycle is completed. But in Event Counter and Timer modes, the TON can only be reset by application program.

R to F Converter Mode

The TMRAL, TMRAH, TMRBL and TMRBH are composed of the R to F converter when AD_TMB bit is set to 1. The R to F converter contains two 16-bit programmable count-up counters, Timer A and Timer B.



R to F Converter

In the R to F Converter mode, the timer A clock source is recommended to come from the system clock by configuring the TM[1:0] bits as 10. The timer B clock source comes from the R to F circuit 0/1 output or internal 128kHz LIRC2 oscillator selected by the TMBSEL bit in the ADCR register. The OVB_OVAB bit in the ADCR register determines whether timer A or timer B overflows, then the RTMRF bit is set high and timer interrupt occurs.

When the TON bit is set to "1" the timer A and timer B will start counting until timer A or timer B overflows, the timer/event counter generates the interrupt request flag and the timer A and timer B stop counting and reset the TON bit to "0" at the same time. If the TON bit is "1", the TMRAH, TMRAL, TMRBH and TMRBL cannot be read or written to. Only when the timer/event counter is off and when the instruction "MOV" is used can the TMRAL, TMRAH, TMRBL and TMRBH registers be read or written to.

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Write/Read Procedures

Writing TMRAH/TMRBH makes the starting value be placed in the timer A or timer B and reading TMRAH/TMRBH retrieves the contents of the timer A or timer B. Writing TMRAL/TMRBL only writes the data into a low byte buffer, and writing TMRAH/TMRBH will write the data and the contents of the low byte buffer into the timer A or timer B (16-bit) simultaneously. The timer A or timer B is changed by writing TMRAH/TMRBH operations and writing TMRAL/TMRBL will keep the timer A or timer B unchanged.

Reading TMRAH/TMRBH will also latch the TMRAL/TMRBL into the low byte buffer to avoid false timing problem. Reading TMRAL/TMRBL returns the contents of the low byte buffer. In other words, the low byte of timer A or timer B cannot be read directly. It must read the TMRAH/TMRBH first to make the low byte contents of timer A or timer B be latched into the buffer.

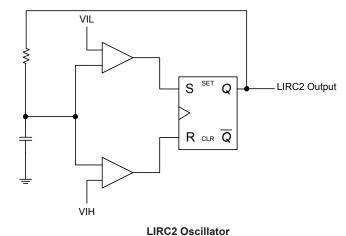
TMRAL&TMRAH/TMRBL&TMRBH Register Access Considerations:

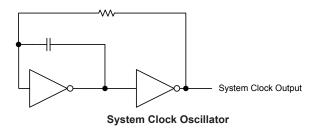
- 1. Writing Data to these registers: Write data to low byte TMRAL/TMRBL first and then write data to the high byte TMRAH/TMRBH.
- 2. Reading Data from these registers: Read data from the high byte TMRAH/ TMRBH first and then read data from the low byteTMRAL/TMRBL.
- 3. Accessing these register pair without following the access procedures as described above will result in unpredictable values.

System Clock Oscillator Calibration

"System Clock Oscillator" is used to oscillating the clock signal to be the MCU system clock. It comsumes fewer power than other oscillators. The system clock is also the reference clock to count the real time in order to decreasing power consumption. However, the system clock is not accurate in variant operating voltage or in variant ambient temperature. Hence, the system clock shall be calibrated first.

LIRC2 Oscillator is more accurate than System Clock Oscillator in variant operating voltage or in variant ambient temperature, so LIRC2 can be used to calibrate the System Clock Oscillator.





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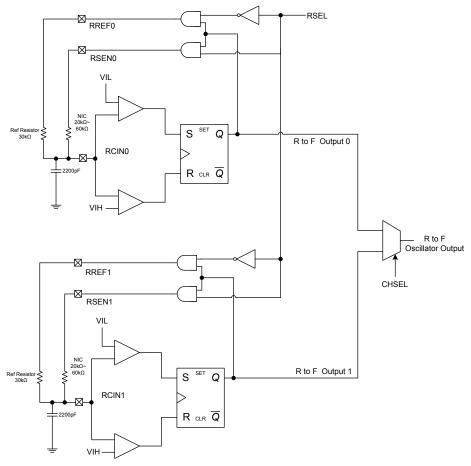
The Calibration can be acheieved by executing the steps below.

- Step1: Select "System clock" to the clock source of Timer A and select "LIRC2" to the clock source of Timer B.
- Step2: Assign the values of registers TMRAL and TMRAH.
- Step3: Select Timer A overflow occurance as the interrupt source and then activate Timer A in timer mode and Timer B simultaneously.
- Step4: Once Timer A overflow occur, stop counting TMRA and TMRB automatically and then calculate the variance of TMRA and TMRB.

Step5: System clock can be calibrated by the variance just calculated in the application program.

In order to decrease power consumption, LIRC2 is advised to be turned on while doing System Clock pulse width measurement and turned off while finishing System Clock pulse width measurement.

Temperature Measurement



R to F Oscillator Output

"R to F Oscillator" is used to oscillate the clock whose frequency is decided by the external resistor. Take the reference to the Block diagram "R to F Oscillator", a reference resistor "Ref Resistor" is supplied to "R to F Oscillator" to produce an output clock frequency as a reference frequency. The Thermistor "NIC" is supplied to "R to F Oscillator" to produce an output clock frequency and then compare that frequency with the reference frequency to measure the temperature.

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The temperature measurement can be achieved by following steps.

- Step1: Select "System clock" to the clock source of Timer A and select "R to F Oscillator" to the clock source of Timer B.
- Step2: Select the RREF path as the input RC path of "R to F Oscillator" by clearing RSEL control bit.
- Step3: Assign the values of registers TMRAL and TMRAH
- Step4: Select Timer A overflow occurance as the interrupt source and then activate Timer A in timer mode and Timer B.
- Step5: Once TMRA overflow occur, stop counting TMRA and TMRB automatically and then calculate the variance of TMRA and TMRB. The variance is said to be "Variance 1"
- Step6: Select the RSEN path as the input RC path of "R to F Oscillator" by setting RSEL control bit to 1 and then redo the actions from step 4 to step 5. Furthermore, the variance can be obtained and said to be "Variance 2"
- Step7: The output frequency difference of "RSEN path" and "RREF path" in "R to F Oscillator" can be calculated by comparison of "Variance 1" and "Variance 2" in application program. Furthermore, the NIC temperature can be obtained from that frequency difference just calculated.

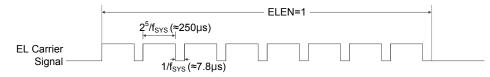
TMRAL/TMRAH/TMRBL/TMRBH Reload Considerations

When in the R to F converter mode, mainly the Timer A clock is from the system clock while the Timer B clock is from the R to F oscillator output. When a time-out condition occurs in the Timer A, the Timer B will be turned off and its current value is used as the R to F conversion data. Care must be taken that the Timer A and Timer B will not reload the preset data which is the difference from other general timer operations.

EL Carrier Output

One EL pin which is the EL carrier signal output pin is provided in the device. The PA1 is pinshared with the EL pin. Before enable the EL carrier output function, make sure the PAS0 register is configured correctly to select the EL pin function.

If the EL carrier output is enable, it will start output the following EL carrier signal. The output high period is $32/f_{SYS}$, and the output low level period is $1/f_{SYS}$. The following diagram is based on the f_{SYS} set to 128kHz.



EL Timing (fsys=128kHz)

ELC Register

Bit	7	6	5	4	3	2	1	0
Name	_	_	_	_	_	_	_	ELEN
R/W	_	_	_	_	_	_	_	R/W
POR	_	_	_	_	_	_	_	0

Bit 7~1 Unimplemented, read as "0"

Bit 0 **ELEN**: EL Carrier output function enable/disable control

0: Disable 1: Enable

When ELEN is set high to enable the EL carrier signal output, the EL pin will start output the signal, by 32/f_{SYS} high and 1/f_{SYS} low signal.

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Interrupts

Interrupts are an important part of any microcontroller system. When an external event or an internal function such as a Timer Module requires microcontroller attention, their corresponding interrupt will enforce a temporary suspension of the main program allowing the microcontroller to direct attention to their respective needs. The device contains several external interrupt and internal interrupt functions. The external interrupt is generated by the action of the external INT0 and INT1 pins, while the internal interrupts are generated by various internal functions such as the R to F Converter, Compact Timer Module (CTM), Time Bases, LVD and the EEPROM write operation.

Interrupt Registers

Overall interrupt control, which basically means the setting of request flags when certain microcontroller conditions occur and the setting of interrupt enable bits by the application program, is controlled by a series of registers, located in the Special Purpose Data Memory, as shown in the accompanying table. The interrupt registers fall into two categories. The first is the INTC0~INTC2 registers which setup the primary interrupts, the second is an INTEG register to setup the external interrupt trigger edge type.

Each register contains a number of enable bits to enable or disable individual registers as well as interrupt flags to indicate the presence of an interrupt request. The naming convention of these follows a specific pattern. First is listed an abbreviated interrupt type, then the (optional) number of that interrupt followed by either an "E" for enable/disable bit or "F" for request flag.

Function	Enable Bit	Request Flag	Notes
Global	EMI	_	_
R to F Converter	RTMRE	RTMRF	_
INTn Pin	INTnE	INTnF	n=0~1
Time Base	TBnE	TBnF	n=0~1
LVD	LVE	LVF	_
EEPROM	DEE	DEF	_
Timer Module	CTMAE	CTMAF	
Timer would	CTMPE	CTMPF	_

Interrupt Register Bit Naming Conventions

Register		Bit								
Name	7	6	5	4	3	2	1	0		
INTEG	_	_	_	_	INT1S1	INT1S0	INT0S1	INT0S0		
INTC0	_	RTMRF	INT1F	INT0F	RTMRE	INT1E	INT0E	EMI		
INTC1	TB0F	LVF	CTMAF	CTMPF	TB0E	LVE	CTMAE	CTMPE		
INTC2	_	_	DEF	TB1F	_	_	DEE	TB1E		

Interrupt Register List

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• INTEG Register

Bit	7	6	5	4	3	2	1	0
Name	_	_	_	_	INT1S1	INT1S0	INT0S1	INT0S0
R/W	_	_	_	_	R/W	R/W	R/W	R/W
POR	_	_	_	_	0	0	0	0

Bit 7~4 Unimplemented, read as "0"

Bit 3~2 INT1S1~INT1S0: Defines INT1 interrupt active edge

00: Disabled 01: Rising Edge 10: Falling Edge 11: Dual Edges

Bit 1~0 INT0S1~INT0S0: Defines INT0 interrupt active edge

00: Disabled 01: Rising Edge 10: Falling Edge 11: Dual Edges

• INTC0 Register

Bit	7	6	5	4	3	2	1	0
Name	_	RTMRF	INT1F	INT0F	RTMRE	INT1E	INT0E	EMI
R/W	_	R/W	R/W	R/W	R/W	R/W	R/W	R/W
POR	_	0	0	0	0	0	0	0

Bit 7 Unimplemented, read as "0"

Bit 6 RTMRF: R to F converter timer overflow interrupt request flag

0: No request1: Interrupt request

Bit 5 **INT1F**: INT1 interrupt request flag

0: No request1: Interrupt request

Bit 4 **INT0F**: INT0 interrupt request flag

0: No request
1: Interrupt request

Bit 3 RTMRE: R to F timer interrupt control

0: Disable 1: Enable

Bit 2 INT1E: INT1 interrupt control

0: Disable 1: Enable

Bit 1 **INT0E**: INT0 interrupt control

0: Disable 1: Enable

Bit 0 **EMI**: Global Interrupt Control

0: Disable 1: Enable



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• INTC1 Register

Bit 6

Bit	7	6	5	4	3	2	1	0
Name	TB0F	LVF	CTMAF	CTMPF	TB0E	LVE	CTMAE	CTMPE
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
POR	0	0	0	0	0	0	0	0

Bit 7 **TB0F**: Time Base 0 interrupt request flag

0: No request1: Interrupt request

LVF: LVD interrupt request flag

0: No request1: Interrupt request

Bit 5 CTMAF: CTM comparator A match interrupt request flag

0: No request1: Interrupt request

Bit 4 CTMPF: CTM comparator P match interrupt request flag

0: No request1: Interrupt request

Bit 3 **TB0E**: Time Base 0 interrupt control

0: Disable 1: Enable

Bit 2 LVE: LVD interrupt control

0: Disable 1: Enable

Bit 1 CTMAE: CTM comparator A match interrupt control

0: Disable 1: Enable

Bit 0 CTMPE: CTM comparator P match interrupt control

0: Disable 1: Enable

• INTC2 Register

Bit	7	6	5	4	3	2	1	0
Name	_	_	DEF	TB1F	_	_	DEE	TB1E
R/W	_	_	R/W	R/W	_	_	R/W	R/W
POR	_	_	0	0	_	_	0	0

Bit 7~6 Unimplemented, read as "0"

Bit 5 **DEF**: Data EEPROM interrupt request flag

0: No request 1: Interrupt request

Bit 4 TB1F: Time Base 1 interrupt request flag

0: No request1: Interrupt request

Bit 3~2 Unimplemented, read as "0"

Bit 1 **DEE**: Data EEPROM interrupt control

0: Disable1: Enable

Bit 0 **TB1E**: Time Base 1 interrupt control

0: Disable 1: Enable

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Interrupt Operation

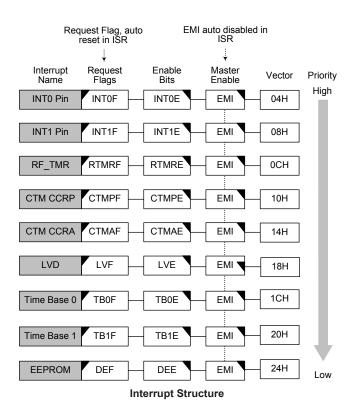
When the conditions for an interrupt event occur, such as a TM Comparator P or Comparator A match etc, the relevant interrupt request flag will be set. Whether the request flag actually generates a program jump to the relevant interrupt vector is determined by the condition of the interrupt enable bit. If the enable bit is set high then the program will jump to its relevant vector; if the enable bit is zero then although the interrupt request flag is set an actual interrupt will not be generated and the program will not jump to the relevant interrupt vector. The global interrupt enable bit, if cleared to zero, will disable all interrupts.

When an interrupt is generated, the Program Counter, which stores the address of the next instruction to be executed, will be transferred onto the stack. The Program Counter will then be loaded with a new address which will be the value of the corresponding interrupt vector. The microcontroller will then fetch its next instruction from this interrupt vector. The instruction at this vector will usually be a "JMP" which will jump to another section of program which is known as the interrupt service routine. Here is located the code to control the appropriate interrupt. The interrupt service routine must be terminated with a "RETI", which retrieves the original Program Counter address from the stack and allows the microcontroller to continue with normal execution at the point where the interrupt occurred.

The various interrupt enable bits, together with their associated request flags, are shown in the accompanying diagrams with their order of priority. Once an interrupt subroutine is serviced, all the other interrupts will be blocked, as the global interrupt enable bit, EMI bit will be cleared automatically. This will prevent any further interrupt nesting from occurring. However, if other interrupt requests occur during this interval, although the interrupt will not be immediately serviced, the request flag will still be recorded.

If an interrupt requires immediate servicing while the program is already in another interrupt service routine, the EMI bit should be set after entering the routine, to allow interrupt nesting. If the stack is full, the interrupt request will not be acknowledged, even if the related interrupt is enabled, until the Stack Pointer is decremented. If immediate service is desired, the stack must be prevented from becoming full. In case of simultaneous requests, the accompanying diagram shows the priority that is applied. All of the interrupt request flags when set will wake-up the device if it is in SLEEP or IDLE Mode, however to prevent a wake-up from occurring the corresponding flag should be set before the device is in SLEEP or IDLE Mode.

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External Interrupts

The external interrupts are controlled by signal transitions on the pins INT0~INT1. An external interrupt request will take place when the external interrupt request flags, INT0F~INT1F, are set, which will occur when a transition, whose type is chosen by the edge select bits, appears on the external interrupt pins. To allow the program to branch to its respective interrupt vector address, the global interrupt enable bit, EMI, and respective external interrupt enable bit, INT0E~INT1E, must first be set. Additionally the correct interrupt edge type must be selected using the INTEG register to enable the external interrupt function and to choose the trigger edge type. As the external interrupt pins are pin-shared with I/O pins, they can only be configured as external interrupt pins if their external interrupt enable bit in the corresponding interrupt register has been set. The pin must also be setup as an input by setting the corresponding bit in the port control register as well as the relevant pin-shared function selection bits. When the interrupt is enabled, the stack is not full and the correct transition type appears on the external interrupt pin, a subroutine call to the external interrupt vector, will take place. When the interrupt is serviced, the external interrupt request flags, INT0F~INT1F, will be automatically reset and the EMI bit will be automatically cleared to disable other interrupts. Note that any pull-high resistor selections on the external interrupt pins will remain valid even if the pin is used as an external interrupt input.

The INTEG register is used to select the type of active edge that will trigger the external interrupt. A choice of either rising or falling or both edge types can be chosen to trigger an external interrupt. Note that the INTEG register can also be used to disable the external interrupt function.



R to F Converter Interrupt

An R to F converter interrupt request will take place when the RF_TMR Interrupt request flag, RTMRF, is set, which occurs when a timer A or timer B overflow. To allow the program to branch to its respective interrupt vector address, the global interrupt enable bit, EMI, and the RF_TMR Interrupt enable bit, RTMRE, must first be set. When the interrupt is enabled, the stack is not full and a timer A or timer B overflow occurs, a subroutine call to the RF_TMR Interrupt vector, will take place. When the RF_TMR Interrupt is serviced, the EMI bit will be automatically cleared to disable other interrupts and the RF_TMR interrupt request flag will be also automatically cleared.

Timer Module Interrupts

The CTM has two interrupts, CCRP and CCRA interrupts, each of which has its own interrupt vector. There are two interrupt request flags CTMPF and CTMAF and two enable bits CTMPE and CTMAE. A CTM interrupt request will take place when any of the CTM request flags is set, a situation which occurs when a CTM comparator P or comparator A match situation happens.

To allow the program to branch to its respective interrupt vector address, the global interrupt enable bit, EMI, and the respective CTM Interrupt enable bit, CTMAE or CTMPE, must first be set. When the interrupt is enabled, the stack is not full and a CTM comparator match situation occurs, a subroutine call to the relevant CTM CCRA or CCRP Interrupt vector location, will take place. When the CTM interrupt is serviced, the EMI bit will be automatically cleared to disable other interrupts, the CTM interrupt request flag will will be also automatically cleared.

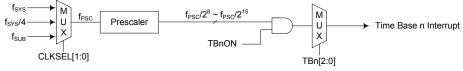
LVD Interrupt

An LVD Interrupt request will take place when the LVD Interrupt request flag, LVF, is set, which occurs when the Low Voltage Detector function detects a low power supply voltage. To allow the program to branch to its respective interrupt vector address, the global interrupt enable bit, EMI, and Low Voltage Interrupt enable bit, LVE, must first be set. When the interrupt is enabled, the stack is not full and a low voltage condition occurs, a subroutine call to the LVD Interrupt vector, will take place. When the Low Voltage Interrupt is serviced, the EMI bit will be automatically cleared to disable other interrupts, and the LVD interrupt request flag will be also automatically cleared.

Time Base Interrupts

The function of the Time Base interrupts is to provide regular time signal in the form of an internal interrupt. They are controlled by the overflow signals from their respective timer functions. When these happens their respective interrupt request flags, TB0F or TB1F will be set. To allow the program to branch to their respective interrupt vector addresses, the global interrupt enable bit, EMI and Time Base enable bits, TB0E or TB1E, must first be set. When the interrupt is enabled, the stack is not full and the Time Base overflows, a subroutine call to their respective vector locations will take place. When the interrupt is serviced, the respective interrupt request flag, TB0F or TB1F, will be automatically reset and the EMI bit will be cleared to disable other interrupts.

The purpose of the Time Base Interrupt is to provide an interrupt signal at fixed time periods. Its clock source, f_{PSC}, originates from the internal clock source f_{SYS}, f_{SYS}/4 or f_{SUB} and then passes through a divider, the division ratio of which is selected by programming the appropriate bits in the TB0C and TB1C registers to obtain longer interrupt periods whose value ranges. The clock source which in turn controls the Time Base interrupt period is selected using the CLKSEL[1:0] bits in the PSCR register.



Time Base Interrupts (n=0 ~ 1)

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• PSCR Register

Bit	7	6	5	4	3	2	1	0
Name	_	_	_	_	_	_	CLKSEL1	CLKSEL0
R/W	_	_	_	_	_	_	R/W	R/W
POR	_	_	_	_	_	_	0	0

Bit 7~2 Unimplemented, read as "0"

Bit 1~0 CLKSEL1~CLKSEL0: Prescaler clock source f_{PSC} selection

00: f_{SYS} 01: f_{SYS}/4 1x: f_{SUB}

• TB0C Register

Bit	7	6	5	4	3	2	1	0
Name	TB0ON	_	_	_	_	TB02	TB01	TB00
R/W	R/W	_	_	_	_	R/W	R/W	R/W
POR	0	_	_	_	_	0	0	0

Bit 7 **TB0ON**: Time Base 0 Enable Control

0: Disable 1: Enable

Bit 6~3 Unimplemented, read as "0"

Bit 2~0 **TB02~TB00**: Time Base 0 time-out period selection

 $\begin{array}{l} 000:\ 2^8/f_{PSC} \\ 001:\ 2^9/f_{PSC} \\ 010:\ 2^{10}/f_{PSC} \\ 011:\ 2^{11}/f_{PSC} \\ 100:\ 2^{12}/f_{PSC} \\ 101:\ 2^{13}/f_{PSC} \\ 101:\ 2^{14}/f_{PSC} \\ 111:\ 2^{15}/f_{PSC} \end{array}$

• TB1C Register

Bit	7	6	5	4	3	2	1	0
Name	TB10N	_	_	_	_	TB12	TB11	TB10
R/W	R/W	_	_	_	_	R/W	R/W	R/W
POR	0	_	_	_	_	0	0	0

Bit 7 **TB1ON**: Time Base 1 Enable Control

0: Disable 1: Enable

Bit 6~3 Unimplemented, read as "0"

Bit 2~0 TB12~TB10: Time Base 1 time-out period selection

 $\begin{array}{l} 000:\ 2^8/f_{PSC} \\ 001:\ 2^9/f_{PSC} \\ 010:\ 2^{10}/f_{PSC} \\ 011:\ 2^{11}/f_{PSC} \\ 100:\ 2^{12}/f_{PSC} \\ 101:\ 2^{13}/f_{PSC} \\ 101:\ 2^{14}/f_{PSC} \\ 111:\ 2^{15}/f_{PSC} \end{array}$



EEPROM Write Interrupt

An EEPROM Write Interrupt will take place when the EEPROM Interrupt request flag, DEF, is set, which occurs when an EEPROM Write cycle ends. To allow the program to branch to its respective interrupt vector address, the global interrupt enable bit, EMI, and EEPROM Interrupt enable bit, DEE, must first be set. When the interrupt is enabled, the stack is not full and an EEPROM Write cycle ends, a subroutine call to the respective EEPROM Interrupt vector, will take place. When the EEPROM Interrupt is serviced, the EEPROM write interrupt flag will be automatically cleared and the EMI bit will be also automatically cleared to disable other interrupts.

Interrupt Wake-up Function

Each of the interrupt functions has the capability of waking up the microcontroller when in the SLEEP or IDLE Mode. A wake-up is generated when an interrupt request flag changes from low to high and is independent of whether the interrupt is enabled or not. Therefore, even though the device is in the SLEEP or IDLE Mode and its system oscillator stopped, situations such as external edge transitions on the external interrupt pins or a low power supply voltage may cause their respective interrupt flag to be set high and consequently generate an interrupt. Care must therefore be taken if spurious wake-up situations are to be avoided. If an interrupt wake-up function is to be disabled then the corresponding interrupt request flag should be set high before the device enters the SLEEP or IDLE Mode. The interrupt enable bits have no effect on the interrupt wake-up function.

Programming Considerations

By disabling the relevant interrupt enable bits, a requested interrupt can be prevented from being serviced, however, once an interrupt request flag is set, it will remain in this condition in the interrupt register until the corresponding interrupt is serviced or until the request flag is cleared by the application program.

It is recommended that programs do not use the "CALL" instruction within the interrupt service subroutine. Interrupts often occur in an unpredictable manner or need to be serviced immediately. If only one stack is left and the interrupt is not well controlled, the original control sequence will be damaged once a CALL subroutine is executed in the interrupt subroutine.

Every interrupt has the capability of waking up the microcontroller when it is in SLEEP or IDLE Mode, the wake up being generated when the interrupt request flag changes from low to high. If it is required to prevent a certain interrupt from waking up the microcontroller then its respective request flag should be first set high before enter SLEEP or IDLE Mode.

As only the Program Counter is pushed onto the stack, then when the interrupt is serviced, if the contents of the accumulator, status register or other registers are altered by the interrupt service program, their contents should be saved to the memory at the beginning of the interrupt service routine.

To return from an interrupt subroutine, either a RET or RETI instruction may be executed. The RETI instruction in addition to executing a return to the main program also automatically sets the EMI bit high to allow further interrupts. The RET instruction however only executes a return to the main program leaving the EMI bit in its present zero state and therefore disabling the execution of further interrupts.

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LCD Driver

For large volume applications, which incorporate an LCD in their design, the use of a custom display rather than a more expensive character based display reduces costs significantly. However, the corresponding COM and SEG signals required, which vary in both amplitude and time, to drive such a custom display require many special considerations for proper LCD operation to occur. This device contains an LCD Driver function, which with their internal LCD signal generating circuitry and various options will automatically generate these time and amplitude varying signals to provide a means of direct driving and easy interfacing to a range of custom LCDs.

This device includes a wide range of options to enable LCD displays of various types to be driven. The table shows the range of options available across the device range.

Driver No.	Duty	Bias Level	Bias Type	Waveform Type
22×2	1/2	1/0	C to up a	A == D
21×3	1/3	1/2	C type	A or B

LCD Driver Output Selection

LCD Display Memory

An area of Data Memory is especially reserved for use for the LCD display data. This data area is known as the LCD Display Memory. Any data written here will be automatically read by the internal display driver circuits, which will in turn automatically generate the necessary LCD driving signals. Therefore any data written into this Memory will be immediately reflected into the actual display connected to the microcontroller.

This device provides an area of embedded data memory for the LCD display. This area is located at 80H to 95H in Bank 4 of the Data Memory. To access the LCD Display Memory therefore requires first that Bank 4 is selected by writing a value of 04H to the BP register. After this, the memory can then be accessed by using indirect addressing through the use of MP1. With Bank 4 selected, then using MP1 to read or write to the memory area, from 80H to 95H, will result in operations to the LCD memory. Directly addressing the Display Memory is not applicable and will result in a data access to the Bank 0 General Purpose Data Memory.

The LCD display can be read and written to only by indirect and addressing mode using MP1. When data is written into the display data area, it is automatically read by the LCD driver which then generates the corresponding LCD driving signals. To turn the display on or off, a "1" or a "0" is written to the corresponding bit of the display memory, respectively. The figure illustrates the mapping between the display memory and LCD pattern for the device.

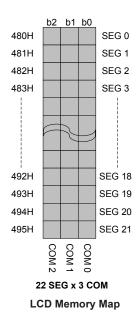
The unimplemented LCD RAM bits cannot be used as general purpose RAM for application. For example, if the LCD duty is selected as 1/2 duty (COM0~COM1 are used), the COM bit 2~bit 7 will be read as 0 only.

LCD Clock Source

The LCD clock source is the internal clock signal, f_{SUB} , divided by 8, using an internal divider circuit. For proper LCD operation, this arrangement is provided to generate an ideal LCD clock frequency of 4kHz.

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LCD Registers

A Control Register LCDC is used to control the various setup features of the LCD Driver. The TYPE bit in the LCDC register is used to select whether Type A or Type B LCD control signals are used. PUMPEN bit is used to control the internal charge pump enable or disable and then to control the power to supply the LCD panel. The DTYC bit is used for the duty selection. The LCDEN bit provides the overall LCD enable/disable function, which is only effective when this device is in the Normal or Idle Mode. If this device is in the Sleep Mode then the display will always be disabled.

LCDC Register

Bit	7	6	5	4	3	2	1	0
Name	TYPE	_	_	_	_	PUMPEN	DTYC	LCDEN
R/W	R/W	_	_	_	_	R/W	R/W	R/W
POR	0	_	_	_	_	0	0	0

Bit 7 TYPE: LCD Waveform Type Selection

0: Type A 1: Type B

Bit 6~3 Unimplemented, read as "0"

Bit 2 **PUMPEN**: LCD pump control

0: Disable, PLCD=VA=V_{DD} or 2×V_{DD}

1: Enable, PLCD=VA=2×V_{DD}

When both the PUMPEN and LCDEN bits are 0, the voltage PLCD=VA= V_{DD} ; if the PUMPEN bit is 0 while the LCDEN bit is 1, the voltage PLCD=VA= $2\times V_{DD}$.Note When the LCDEN bit is set to 1 to enable the LCD function, the PUMPEN bit must also be set to 1 to enable the charge pump circuit to make sure that the LCD function can operate normally.

Bit 1 **DTYC**: LCD duty selection

0: 1/3 Duty (COM0~COM2) 1: 1/2 Duty (COM0~COM1)

The unused COM2 pin when 1/2 Duty is selected is used as segment function.

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Bit 0 LCDEN: LCD Enable Control

0: Disable 1: Enable

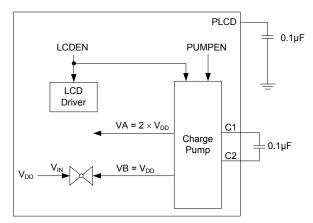
In the Normal or Idle mode, the LCD on/off function can be controlled by this bit. In the Sleep mode, the LCD is always off. Note that the LCD will be disabled and the pump circuit will be enabled regardless of the PUMPEN and LCDEN bit values when the device enters the ICP Programming mode.

LCD Voltage Source and Biasing

The time and amplitude varying signals generated by the LCD Driver function require the generation of several voltage levels for their operation. The device uses the C type biasing.

The LCD voltage source is derived from the internal voltage V_{DD} to generate the required biasing voltages. The C type biasing scheme uses an internal charge pump circuit can generate voltages higher than what is supplied. This feature is useful in applications where the microcontroller supply voltage is less than the supply voltage required by the LCD. An additional charge pump capacitor must also be connected between pins C1 and C2 to generate the necessary voltage levels.

Three internally generated voltage levels V_{SS} , VA and VB are utilised. As the power source is from VDD, the voltage VA is generated internally and has a value of $2 \times V_{DD}$. The VB has a value of V_{DD} , the PLCD pin has the same voltage as the VA.



C Type 1/2 Bias Voltage Scheme

LCD Reset Function

The LCD has an internal reset function that is an OR function of the inverted LCDEN bit in the LCDC register and the SLEEP function. Clearing the LCDEN bit to zero will also reset the LCD function. The LCD function will be reset after the device enters the SLEEP mode even if the LCDEN bit is set to 1 to enable the LCD driver function.

When the LCDEN bit is set to 1 to enable the LCD driver and then an MCU reset occurs, the LCD driver will be reset and the COM and SEG outputs will be in a floating state during the MCU reset duration. The reset operation will take a time of $t_{RSTD}+t_{SST}$. Refer to the A.C. Characteristics for t_{RSTD} and t_{SST} details.

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MCU Reset	SLEEP Mode	LCDEN	LCD Reset	COM & SEG Voltage Level
No	Off	1	No	Normal Operation
No	Off	0	Yes	Low
No	On	х	Yes	Low
Yes	х	х	Yes	Floating

Notes: 1. The Watchdog time-out reset in the IDLE or SLEEP Mode is excluded from the MCU Reset conditions.

2. "x": Don't care

LCD Reset Status

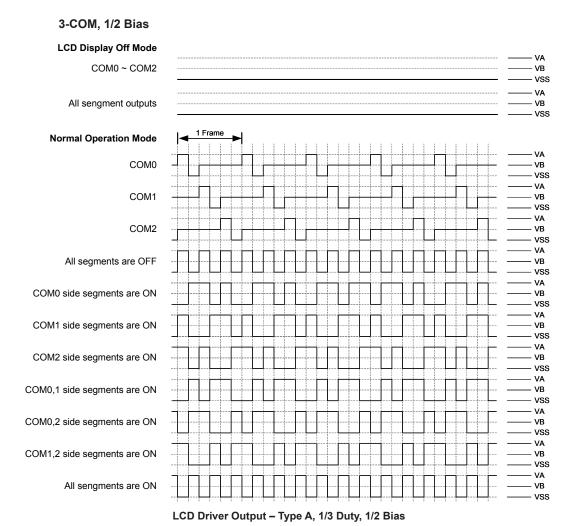
LCD Driver Output

The number of COM and SEG outputs supplied by the LCD driver, as well as its wave type selections, is dependent upon how the LCD control bits are programmed.

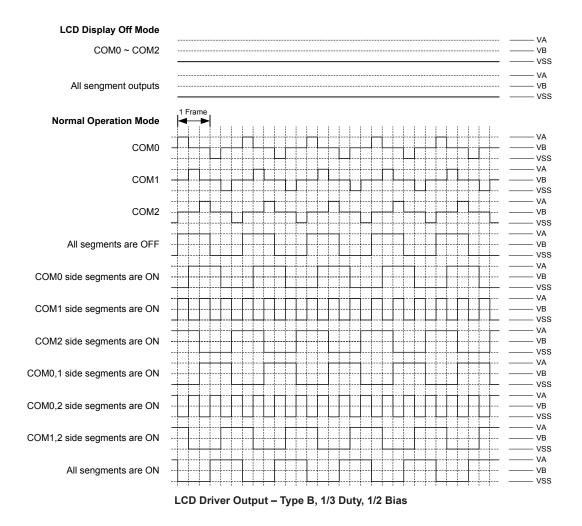
The nature of Liquid Crystal Displays require that only AC voltages can be applied to their pixels as the application of DC voltages to LCD pixels may cause permanent damage. For this reason the relative contrast of an LCD display is controlled by the actual RMS voltage applied to each pixel, which is equal to the RMS value of the voltage on the COM pin minus the voltage applied to the SEG pin. This differential RMS voltage must be greater than the LCD saturation voltage for the pixel to be on and less than the threshold voltage for the pixel to be off.

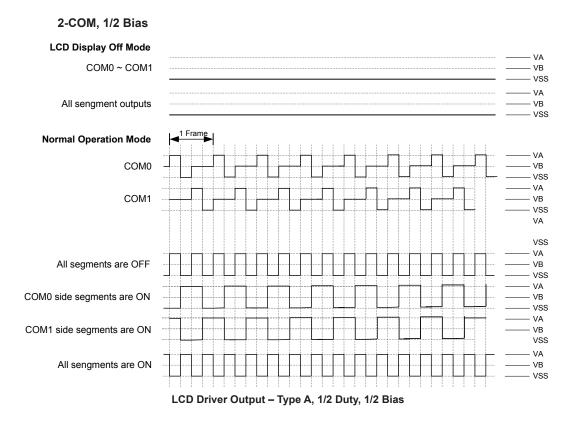
The requirement to limit the DC voltage to zero and to control as many pixels as possible with a minimum number of connections requires that both a time and amplitude signal is generated and applied to the application LCD. These time and amplitude varying signals are automatically generated by the LCD driver circuits in the microcontroller. What is known as the duty determines the number of common lines used, which are also known as backplanes or COMs. For example, the duty is 1/3 and equates to a COM number of 3, therefore defines the number of time divisions within each LCD signal frame. Two types of signal generation are also provided, known as Type A and Type B, the required type is selected via the TYPE bit in the LCDC register. Type B offers lower frequency signals, however lower frequencies may introduce flickering and influence display clarity.

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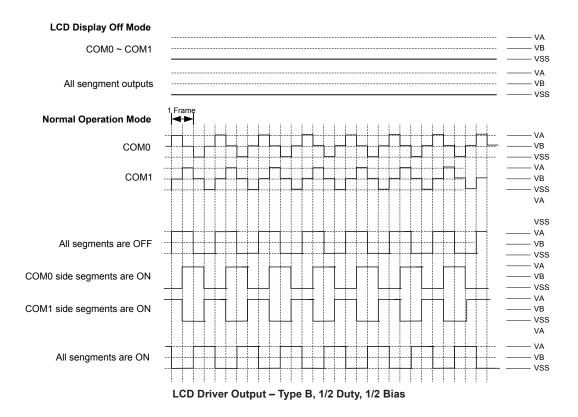














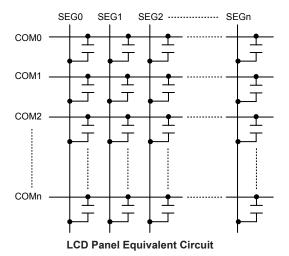
Programming Considerations

Certain precautions must be taken when programming the LCD. One of these is to ensure that the LCD Memory is properly initialised after the microcontroller is powered on. Like the General Purpose Data Memory, the contents of the LCD Memory are in an unknown condition after power-on. As the contents of the LCD Memory will be mapped into the actual display, it is important to initialise this memory area into a known condition soon after applying power to obtain a proper display pattern.

Consideration must also be given to the capacitive load of the actual LCD used in the application. As the load presented to the microcontroller by LCD pixels can be generally modeled as mainly capacitive in nature, it is important that this is not excessive, a point that is particularly true in the case of the COM lines which may be connected to many LCD pixels. The accompanying diagram depicts the equivalent circuit of the LCD.

One additional consideration that must be taken into account is what happens when the microcontroller enters the SLEEP Mode. The LCDEN control bit in the LCDC register permits the display to be powered off to reduce power consumption. If this bit is zero or if the microcontroller enters the SLEEP mode, the driving signals to the display will cease, producing a blank display pattern but reducing any power consumption associated with the LCD.

After Power-on, note that as the LCDEN bit will be cleared to zero, the display function will be disabled.



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Low Voltage Detector – LVD

The device has a Low Voltage Detector function, also known as LVD. This enables the device to monitor the power supply voltage, V_{DD}, and provides a warning signal should it fall below a certain level. This function may be especially useful in battery applications where the supply voltage will gradually reduce as the battery ages, as it allows an early warning battery low signal to be generated. The Low Voltage Detector also has the capability of generating an interrupt signal.

LVD Register

The Low Voltage Detector function is controlled using a single register with the name LVDC. The LVD has a specified value of 1.15V below which a low voltage condition will be determined. A low voltage condition is indicated when the LVDO bit is set. If the LVDO bit is low, this indicates that the V_{DD} voltage is above the specified low voltage value. The LVDEN bit is used to control the overall on/off function of the low voltage detector. Setting the bit high will enable the low voltage detector. Clearing the bit to zero will switch off the internal low voltage detector circuits. As the low voltage detector will consume a certain amount of power, it may be desirable to switch off the circuit when not in use, an important consideration in power sensitive battery powered applications.

LVDC Register

Bit	7	6	5	4	3	2	1	0
Name	_	_	LVDO	LVDEN	_	_	_	_
R/W	_	_	R	R/W	_	_	_	_
POR	_	_	0	0	_	_	_	_

Bit 7 ~ 6 Unimplemented, read as "0"

Bit 5 LVDO: LVD Output Flag

0: No Low Voltage Detected

1: Low Voltage Detected

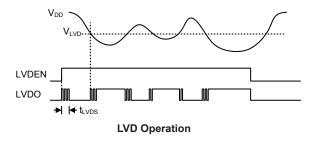
Bit 4 LVDEN: Low Voltage Detector Control

0: Disable 1: Enable

Bit 3~0 Unimplemented, read as "0"

LVD Operation

The Low Voltage Detector function operates by comparing the power supply voltage, V_{DD} , with a pre-specified voltage level of 1.15V. When the power supply voltage, VDD, falls below this predetermined value, the LVDO bit will be set high indicating a low power supply voltage condition. After enabling the Low Voltage Detector, a time delay t_{LVDS} should be allowed for the circuitry to stabilise before reading the LVDO bit. Note also that as the V_{DD} voltage may rise and fall rather slowly, at the voltage nears that of V_{LVD}, there may be multiple bit LVDO transitions.



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The Low Voltage Detector also has its own interrupt, providing an alternative means of low voltage detection, in addition to polling the LVDO bit. The interrupt will only be generated after a delay of t_{LVD} after the LVDO bit has been set high by a low voltage condition. In this case, the LVF interrupt request flag will be set, causing an interrupt to be generated if V_{DD} falls below the specified LVD voltage. This will cause the device to wake-up from the IDLE Mode, however if the Low Voltage Detector wake up function is not required then the LVF flag should be first set high before the device enters the IDLE Mode. When the device enters the SLEEP mode the Low Voltage Detector will disable, even if the LVDEN bit is high.

Configuration Option

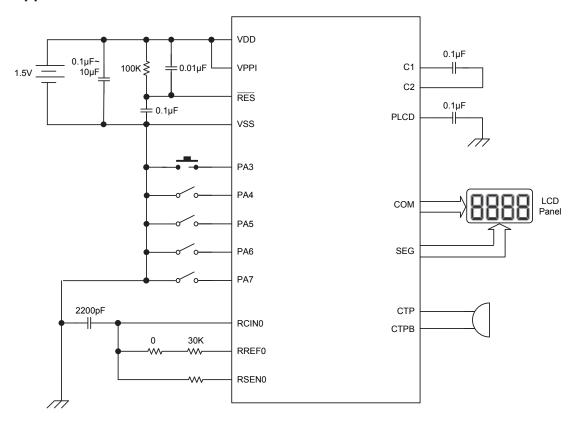
Configuration options refer to certain options within the MCU that are programmed into the device during the programming process. During the development process, these options are selected using the HT-IDE software development tools. As these options are programmed into the device using the hardware programming tools, once they are selected they cannot be changed later using the application program. All options must be defined for proper system function, the details of which are shown in the table.

No.	Options	
Oscillator Option		
	IRC frequency Selection: 32kHz, 64kHz or 128kHz	

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Application Circuits



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Instruction Set

Introduction

Central to the successful operation of any microcontroller is its instruction set, which is a set of program instruction codes that directs the microcontroller to perform certain operations. In the case of Holtek microcontroller, a comprehensive and flexible set of over 60 instructions is provided to enable programmers to implement their application with the minimum of programming overheads.

For easier understanding of the various instruction codes, they have been subdivided into several functional groupings.

Instruction Timing

Most instructions are implemented within one instruction cycle. The exceptions to this are branch, call, or table read instructions where two instruction cycles are required. One instruction cycle is equal to 4 system clock cycles, therefore in the case of an 8MHz system oscillator, most instructions would be implemented within 0.5µs and branch or call instructions would be implemented within 1µs. Although instructions which require one more cycle to implement are generally limited to the JMP, CALL, RET, RETI and table read instructions, it is important to realize that any other instructions which involve manipulation of the Program Counter Low register or PCL will also take one more cycle to implement. As instructions which change the contents of the PCL will imply a direct jump to that new address, one more cycle will be required. Examples of such instructions would be "CLR PCL" or "MOV PCL, A". For the case of skip instructions, it must be noted that if the result of the comparison involves a skip operation then this will also take one more cycle, if no skip is involved then only one cycle is required.

Moving and Transferring Data

The transfer of data within the microcontroller program is one of the most frequently used operations. Making use of three kinds of MOV instructions, data can be transferred from registers to the Accumulator and vice-versa as well as being able to move specific immediate data directly into the Accumulator. One of the most important data transfer applications is to receive data from the input ports and transfer data to the output ports.

Arithmetic Operations

The ability to perform certain arithmetic operations and data manipulation is a necessary feature of most microcontroller applications. Within the Holtek microcontroller instruction set are a range of add and subtract instruction mnemonics to enable the necessary arithmetic to be carried out. Care must be taken to ensure correct handling of carry and borrow data when results exceed 255 for addition and less than 0 for subtraction. The increment and decrement instructions INC, INCA, DEC and DECA provide a simple means of increasing or decreasing by a value of one of the values in the destination specified.

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Logical and Rotate Operation

The standard logical operations such as AND, OR, XOR and CPL all have their own instruction within the Holtek microcontroller instruction set. As with the case of most instructions involving data manipulation, data must pass through the Accumulator which may involve additional programming steps. In all logical data operations, the zero flag may be set if the result of the operation is zero. Another form of logical data manipulation comes from the rotate instructions such as RR, RL, RRC and RLC which provide a simple means of rotating one bit right or left. Different rotate instructions exist depending on program requirements. Rotate instructions are useful for serial port programming applications where data can be rotated from an internal register into the Carry bit from where it can be examined and the necessary serial bit set high or low. Another application which rotate data operations are used is to implement multiplication and division calculations.

Branches and Control Transfer

Program branching takes the form of either jumps to specified locations using the JMP instruction or to a subroutine using the CALL instruction. They differ in the sense that in the case of a subroutine call, the program must return to the instruction immediately when the subroutine has been carried out. This is done by placing a return instruction "RET" in the subroutine which will cause the program to jump back to the address right after the CALL instruction. In the case of a JMP instruction, the program simply jumps to the desired location. There is no requirement to jump back to the original jumping off point as in the case of the CALL instruction. One special and extremely useful set of branch instructions are the conditional branches. Here a decision is first made regarding the condition of a certain data memory or individual bits. Depending upon the conditions, the program will continue with the next instruction or skip over it and jump to the following instruction. These instructions are the key to decision making and branching within the program perhaps determined by the condition of certain input switches or by the condition of internal data bits.

Bit Operations

The ability to provide single bit operations on Data Memory is an extremely flexible feature of all Holtek microcontrollers. This feature is especially useful for output port bit programming where individual bits or port pins can be directly set high or low using either the "SET [m].i" or "CLR [m].i" instructions respectively. The feature removes the need for programmers to first read the 8-bit output port, manipulate the input data to ensure that other bits are not changed and then output the port with the correct new data. This read-modify-write process is taken care of automatically when these bit operation instructions are used.

Table Read Operations

Data storage is normally implemented by using registers. However, when working with large amounts of fixed data, the volume involved often makes it inconvenient to store the fixed data in the Data Memory. To overcome this problem, Holtek microcontrollers allow an area of Program Memory to be set as a table where data can be directly stored. A set of easy to use instructions provides the means by which this fixed data can be referenced and retrieved from the Program Memory.

Other Operations

In addition to the above functional instructions, a range of other instructions also exist such as the "HALT" instruction for Power-down operations and instructions to control the operation of the Watchdog Timer for reliable program operations under extreme electric or electromagnetic environments. For their relevant operations, refer to the functional related sections.

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Instruction Set Summary

The following table depicts a summary of the instruction set categorised according to function and can be consulted as a basic instruction reference using the following listed conventions.

Table Conventions

x: Bits immediate data

m: Data Memory address

A: Accumulator

i: 0~7 number of bits

addr: Program memory address

Mnemonic	Description	Cycles	Flag Affected			
Arithmetic						
ADD A,[m]	Add Data Memory to ACC	1	Z, C, AC, OV			
ADDM A,[m]	Add ACC to Data Memory	1 ^{Note}	Z, C, AC, OV			
ADD A,x	Add immediate data to ACC	1	Z, C, AC, OV			
ADC A,[m]	Add Data Memory to ACC with Carry	1	Z, C, AC, OV			
ADCM A,[m]	Add ACC to Data memory with Carry	1 ^{Note}	Z, C, AC, OV			
SUB A,x	Subtract immediate data from the ACC	1	Z, C, AC, OV			
SUB A,[m]	Subtract Data Memory from ACC	1	Z, C, AC, OV			
SUBM A,[m]	Subtract Data Memory from ACC with result in Data Memory	1 ^{Note}	Z, C, AC, OV			
SBC A,[m]	Subtract Data Memory from ACC with Carry	1	Z, C, AC, OV			
SBCM A,[m]	Subtract Data Memory from ACC with Carry, result in Data Memory	1 ^{Note}	Z, C, AC, OV			
DAA [m]	Decimal adjust ACC for Addition with result in Data Memory	1 ^{Note}	С			
Logic Operation						
AND A,[m]	Logical AND Data Memory to ACC	1	Z			
OR A,[m]	Logical OR Data Memory to ACC	1	Z			
XOR A,[m]	Logical XOR Data Memory to ACC	1	Z			
ANDM A,[m]	Logical AND ACC to Data Memory	1 ^{Note}	Z			
ORM A,[m]	Logical OR ACC to Data Memory	1 ^{Note}	Z			
XORM A,[m]	Logical XOR ACC to Data Memory	1 ^{Note}	Z			
AND A,x	Logical AND immediate Data to ACC	1	Z			
OR A,x	Logical OR immediate Data to ACC	1	Z			
XOR A,x	Logical XOR immediate Data to ACC	1	Z			
CPL [m]	Complement Data Memory	1 Note	Z			
CPLA [m]	Complement Data Memory with result in ACC	1	Z			
Increment & Dec	crement					
INCA [m]	Increment Data Memory with result in ACC	1	Z			
INC [m]	Increment Data Memory	1 ^{Note}	Z			
DECA [m]	Decrement Data Memory with result in ACC	1	Z			
DEC [m]	Decrement Data Memory	1 ^{Note}	Z			
Rotate						
RRA [m]	Rotate Data Memory right with result in ACC	1	None			
RR [m]	Rotate Data Memory right	1 ^{Note}	None			
RRCA [m]	Rotate Data Memory right through Carry with result in ACC	1	С			
RRC [m]	Rotate Data Memory right through Carry	1 ^{Note}	С			
RLA [m]	Rotate Data Memory left with result in ACC	1	None			
RL [m]	Rotate Data Memory left	1 ^{Note}	None			
RLCA [m]	Rotate Data Memory left through Carry with result in ACC	1	С			
RLC [m]	Rotate Data Memory left through Carry	1 ^{Note}	С			

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Mnemonic	Description	Cycles	Flag Affected			
Data Move						
MOV A,[m]	Move Data Memory to ACC	1	None			
MOV [m],A	Move ACC to Data Memory	1 ^{Note}	None			
MOV A,x	Move immediate data to ACC	1	None			
Bit Operation						
CLR [m].i	Clear bit of Data Memory	1 ^{Note}	None			
SET [m].i	Set bit of Data Memory	1 ^{Note}	None			
Branch Operation	1					
JMP addr	Jump unconditionally	2	None			
SZ [m]	Skip if Data Memory is zero	1 ^{Note}	None			
SZA [m]	Skip if Data Memory is zero with data movement to ACC	1 ^{Note}	None			
SZ [m].i	Skip if bit i of Data Memory is zero	1 ^{Note}	None			
SNZ [m].i	Skip if bit i of Data Memory is not zero	1 ^{Note}	None			
SIZ [m]	Skip if increment Data Memory is zero	1 ^{Note}	None			
SDZ [m]	Skip if decrement Data Memory is zero	1 ^{Note}	None			
SIZA [m]	Skip if increment Data Memory is zero with result in ACC	1 ^{Note}	None			
SDZA [m]	Skip if decrement Data Memory is zero with result in ACC	1 ^{Note}	None			
CALL addr	Subroutine call	2	None			
RET	Return from subroutine	2	None			
RET A,x	Return from subroutine and load immediate data to ACC	2	None			
RETI	Return from interrupt	2	None			
Table Read Opera	ation					
TABRD [m]	Read table (specific page) to TBLH and Data Memory	2 ^{Note}	None			
TABRDC [m]	Read table (current page) to TBLH and Data Memory	2 ^{Note}	None			
TABRDL [m]	Read table (last page) to TBLH and Data Memory	2 ^{Note}	None			
Miscellaneous						
NOP	No operation	1	None			
CLR [m]	Clear Data Memory	1 ^{Note}	None			
SET [m]	Set Data Memory	1 ^{Note}	None			
CLR WDT	Clear Watchdog Timer	1	TO, PDF			
CLR WDT1	Pre-clear Watchdog Timer	1	TO, PDF			
CLR WDT2	Pre-clear Watchdog Timer	1	TO, PDF			
SWAP [m]	Swap nibbles of Data Memory	1 ^{Note}	None			
SWAPA [m]	Swap nibbles of Data Memory with result in ACC	1	None			
HALT	Enter power down mode	1	TO, PDF			

Notes: 1. For skip instructions, if the result of the comparison involves a skip then two cycles are required, if no skip takes place only one cycle is required.

- 2. Any instruction which changes the contents of the PCL will also require 2 cycles for execution.
- 3. For the "CLR WDT1" and "CLR WDT2" instructions the TO and PDF flags may be affected by the execution status. The TO and PDF flags are cleared after both "CLR WDT1" and "CLR WDT2" instructions are consecutively executed. Otherwise the TO and PDF flags remain unchanged.

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Instruction Definition

ADC A,[m] Add Data Memory to ACC with Carry

Description The contents of the specified Data Memory, Accumulator and the carry flag are added.

The result is stored in the Accumulator.

Operation $ACC \leftarrow ACC + [m] + C$

Affected flag(s) OV, Z, AC, C

ADCM A,[m] Add ACC to Data Memory with Carry

Description The contents of the specified Data Memory, Accumulator and the carry flag are added.

The result is stored in the specified Data Memory.

Operation $[m] \leftarrow ACC + [m] + C$

Affected flag(s) OV, Z, AC, C

ADD A,[m] Add Data Memory to ACC

Description The contents of the specified Data Memory and the Accumulator are added.

The result is stored in the Accumulator.

Operation $ACC \leftarrow ACC + [m]$ Affected flag(s) OV, Z, AC, C

ADD A,x Add immediate data to ACC

Description The contents of the Accumulator and the specified immediate data are added.

The result is stored in the Accumulator.

Operation $ACC \leftarrow ACC + x$ Affected flag(s) OV, Z, AC, C

ADDM A,[m] Add ACC to Data Memory

Description The contents of the specified Data Memory and the Accumulator are added.

The result is stored in the specified Data Memory.

 $\label{eq:continuous} \begin{array}{ll} \text{Operation} & & [m] \leftarrow ACC + [m] \\ \text{Affected flag(s)} & & \text{OV, Z, AC, C} \end{array}$

AND A,[m] Logical AND Data Memory to ACC

Description Data in the Accumulator and the specified Data Memory perform a bitwise logical AND

operation. The result is stored in the Accumulator.

Operation $ACC \leftarrow ACC "AND" [m]$

Affected flag(s) Z

AND A,x Logical AND immediate data to ACC

Description Data in the Accumulator and the specified immediate data perform a bit wise logical AND

operation. The result is stored in the Accumulator.

Operation $ACC \leftarrow ACC$ "AND" x

Affected flag(s) Z

ANDM A,[m] Logical AND ACC to Data Memory

Description Data in the specified Data Memory and the Accumulator perform a bitwise logical AND

operation. The result is stored in the Data Memory.

Operation $[m] \leftarrow ACC "AND" [m]$

Affected flag(s) Z

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CALL addr Subroutine call

Description Unconditionally calls a subroutine at the specified address. The Program Counter then

increments by 1 to obtain the address of the next instruction which is then pushed onto the stack. The specified address is then loaded and the program continues execution from this new address. As this instruction requires an additional operation, it is a two cycle instruction.

Operation Stack \leftarrow Program Counter + 1

Program Counter ← addr

Affected flag(s) None

CLR [m] Clear Data Memory

Description Each bit of the specified Data Memory is cleared to 0.

Operation $[m] \leftarrow 00H$ Affected flag(s) None

CLR [m].i Clear bit of Data Memory

Description Bit i of the specified Data Memory is cleared to 0.

Operation [m].i \leftarrow 0 Affected flag(s) None

CLR WDT Clear Watchdog Timer

Description The TO, PDF flags and the WDT are all cleared.

Operation WDT cleared

 $TO \leftarrow 0$
PDF $\leftarrow 0$

Affected flag(s) TO, PDF

CLR WDT1 Pre-clear Watchdog Timer

Description The TO, PDF flags and the WDT are all cleared. Note that this instruction works in

conjunction with CLR WDT2 and must be executed alternately with CLR WDT2 to have effect. Repetitively executing this instruction without alternately executing CLR WDT2 will

have no effect.

Operation WDT cleared

 $\begin{array}{l} TO \leftarrow 0 \\ PDF \leftarrow 0 \end{array}$

TO DDE

Affected flag(s) TO, PDF

CLR WDT2 Pre-clear Watchdog Timer

Description The TO, PDF flags and the WDT are all cleared. Note that this instruction works in conjunction

with CLR WDT1 and must be executed alternately with CLR WDT1 to have effect.

Repetitively executing this instruction without alternately executing CLR WDT1 will have no

effect.

Operation WDT cleared

 $TO \leftarrow 0$ $PDF \leftarrow 0$

Affected flag(s) TO, PDF

CPL [m] Complement Data Memory

Description Each bit of the specified Data Memory is logically complemented (1's complement). Bits which

previously contained a 1 are changed to 0 and vice versa.

Operation $[m] \leftarrow \overline{[m]}$

Affected flag(s) Z



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CPLA [m] Complement Data Memory with result in ACC

Description Each bit of the specified Data Memory is logically complemented (1's complement). Bits which

previously contained a 1 are changed to 0 and vice versa. The complemented result is stored in

the Accumulator and the contents of the Data Memory remain unchanged.

Operation $ACC \leftarrow [m]$

Affected flag(s) Z

DAA [m] Decimal-Adjust ACC for addition with result in Data Memory

Description Convert the contents of the Accumulator value to a BCD (Binary Coded Decimal) value

resulting from the previous addition of two BCD variables. If the low nibble is greater than 9 or if AC flag is set, then a value of 6 will be added to the low nibble. Otherwise the low nibble remains unchanged. If the high nibble is greater than 9 or if the C flag is set, then a value of 6 will be added to the high nibble. Essentially, the decimal conversion is performed by adding 00H, 06H, 60H or 66H depending on the Accumulator and flag conditions. Only the C flag may be affected by this instruction which indicates that if the original BCD sum is greater than

100, it allows multiple precision decimal addition.

Operation $[m] \leftarrow ACC + 00H \text{ or}$

 $[m] \leftarrow ACC + 06H \text{ or}$ $[m] \leftarrow ACC + 60H \text{ or}$ $[m] \leftarrow ACC + 66H$

Affected flag(s) C

DEC [m] Decrement Data Memory

Description Data in the specified Data Memory is decremented by 1.

Operation $[m] \leftarrow [m] - 1$

Affected flag(s) Z

DECA [m] Decrement Data Memory with result in ACC

Description Data in the specified Data Memory is decremented by 1. The result is stored in the

Accumulator. The contents of the Data Memory remain unchanged.

Operation $ACC \leftarrow [m] - 1$

Affected flag(s) Z

HALT Enter power down mode

Description This instruction stops the program execution and turns off the system clock. The contents of

the Data Memory and registers are retained. The WDT and prescaler are cleared. The power

down flag PDF is set and the WDT time-out flag TO is cleared.

Operation $TO \leftarrow 0$

 $\text{PDF} \leftarrow 1$

Affected flag(s) TO, PDF

INC [m] Increment Data Memory

Description Data in the specified Data Memory is incremented by 1.

Operation $[m] \leftarrow [m] + 1$

Affected flag(s) Z

INCA [m] Increment Data Memory with result in ACC

Description Data in the specified Data Memory is incremented by 1. The result is stored in the Accumulator.

The contents of the Data Memory remain unchanged.

Operation $ACC \leftarrow [m] + 1$

Affected flag(s) Z

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JMP addr Jump unconditionally

Description The contents of the Program Counter are replaced with the specified address. Program

execution then continues from this new address. As this requires the insertion of a dummy

instruction while the new address is loaded, it is a two cycle instruction.

Operation Program Counter ← addr

Affected flag(s) None

MOV A,[m] Move Data Memory to ACC

Description The contents of the specified Data Memory are copied to the Accumulator.

Operation $ACC \leftarrow [m]$ Affected flag(s) None

MOV A,x Move immediate data to ACC

Description The immediate data specified is loaded into the Accumulator.

Operation $ACC \leftarrow x$ Affected flag(s) None

MOV [m],A Move ACC to Data Memory

Description The contents of the Accumulator are copied to the specified Data Memory.

Operation $[m] \leftarrow ACC$ Affected flag(s) None

NOP No operation

Description No operation is performed. Execution continues with the next instruction.

Operation No operation
Affected flag(s) None

OR A,[m] Logical OR Data Memory to ACC

Description Data in the Accumulator and the specified Data Memory perform a bitwise

logical OR operation. The result is stored in the Accumulator.

Operation $ACC \leftarrow ACC "OR" [m]$

Affected flag(s) Z

OR A,x Logical OR immediate data to ACC

Description Data in the Accumulator and the specified immediate data perform a bitwise logical OR

operation. The result is stored in the Accumulator.

Operation $ACC \leftarrow ACC "OR" x$

Affected flag(s) Z

ORM A,[m] Logical OR ACC to Data Memory

Description Data in the specified Data Memory and the Accumulator perform a bitwise logical OR

operation. The result is stored in the Data Memory.

Operation $[m] \leftarrow ACC "OR" [m]$

Affected flag(s) Z

RET Return from subroutine

Description The Program Counter is restored from the stack. Program execution continues at the restored

address.

Operation Program Counter ← Stack



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RET A,x Return from subroutine and load immediate data to ACC

Description The Program Counter is restored from the stack and the Accumulator loaded with the specified

immediate data. Program execution continues at the restored address.

Operation Program Counter ← Stack

 $ACC \leftarrow x$

Affected flag(s) None

RETI Return from interrupt

Description The Program Counter is restored from the stack and the interrupts are re-enabled by setting the

EMI bit. EMI is the master interrupt global enable bit. If an interrupt was pending when the RETI instruction is executed, the pending Interrupt routine will be processed before returning

to the main program.

Operation Program Counter ← Stack

 $EMI \leftarrow 1$

Affected flag(s) None

RL [m] Rotate Data Memory left

Description The contents of the specified Data Memory are rotated left by 1 bit with bit 7 rotated into bit 0.

Operation $[m].(i+1) \leftarrow [m].i; (i=0\sim6)$

 $[m].0 \leftarrow [m].7$

Affected flag(s) None

RLA [m] Rotate Data Memory left with result in ACC

Description The contents of the specified Data Memory are rotated left by 1 bit with bit 7 rotated into bit 0.

The rotated result is stored in the Accumulator and the contents of the Data Memory remain

unchanged.

Operation ACC.(i+1) \leftarrow [m].i; (i=0 \sim 6)

 $ACC.0 \leftarrow [m].7$

Affected flag(s) None

RLC [m] Rotate Data Memory left through Carry

Description The contents of the specified Data Memory and the carry flag are rotated left by 1 bit. Bit 7

replaces the Carry bit and the original carry flag is rotated into bit 0.

Operation $[m].(i+1) \leftarrow [m].i; (i=0\sim6)$

 $[m].0 \leftarrow C$

 $C \leftarrow [m].7$

Affected flag(s) C

RLCA [m] Rotate Data Memory left through Carry with result in ACC

Description Data in the specified Data Memory and the carry flag are rotated left by 1 bit. Bit 7 replaces the

Carry bit and the original carry flag is rotated into the bit 0. The rotated result is stored in the

Accumulator and the contents of the Data Memory remain unchanged.

Operation $ACC.(i+1) \leftarrow [m].i; (i=0\sim6)$

 $ACC.0 \leftarrow C$

 $C \leftarrow [m].7$

Affected flag(s) C

RR [m] Rotate Data Memory right

Description The contents of the specified Data Memory are rotated right by 1 bit with bit 0 rotated into bit 7.

Operation $[m].i \leftarrow [m].(i+1); (i=0\sim6)$

 $[m].7 \leftarrow [m].0$

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RRA [m] Rotate Data Memory right with result in ACC

Description Data in the specified Data Memory is rotated right by 1 bit with bit 0 rotated into bit 7.

The rotated result is stored in the Accumulator and the contents of the Data Memory remain

unchanged.

Operation ACC.i \leftarrow [m].(i+1); (i=0 \sim 6)

 $ACC.7 \leftarrow [m].0$

Affected flag(s) None

RRC [m] Rotate Data Memory right through Carry

Description The contents of the specified Data Memory and the carry flag are rotated right by 1 bit. Bit 0

replaces the Carry bit and the original carry flag is rotated into bit 7.

Operation $[m].i \leftarrow [m].(i+1); (i=0\sim6)$

 $[m].7 \leftarrow C$

 $C \leftarrow [m].0$

Affected flag(s) C

RRCA [m] Rotate Data Memory right through Carry with result in ACC

Description Data in the specified Data Memory and the carry flag are rotated right by 1 bit. Bit 0 replaces

the Carry bit and the original carry flag is rotated into bit 7. The rotated result is stored in the

Accumulator and the contents of the Data Memory remain unchanged.

Operation ACC.i \leftarrow [m].(i+1); (i=0 \sim 6)

 $ACC.7 \leftarrow C$ $C \leftarrow [m].0$

Affected flag(s) C

SBC A,[m] Subtract Data Memory from ACC with Carry

Description The contents of the specified Data Memory and the complement of the carry flag are

subtracted from the Accumulator. The result is stored in the Accumulator. Note that if the result of subtraction is negative, the C flag will be cleared to 0, otherwise if the result is

positive or zero, the C flag will be set to 1.

Operation $ACC \leftarrow ACC - [m] - \overline{C}$

Affected flag(s) OV, Z, AC, C

SBCM A,[m] Subtract Data Memory from ACC with Carry and result in Data Memory

Description The contents of the specified Data Memory and the complement of the carry flag are

subtracted from the Accumulator. The result is stored in the Data Memory. Note that if the result of subtraction is negative, the C flag will be cleared to 0, otherwise if the result is

positive or zero, the C flag will be set to 1.

Operation $[m] \leftarrow ACC - [m] - \overline{C}$

Affected flag(s) OV, Z, AC, C

SDZ [m] Skip if decrement Data Memory is 0

Description The contents of the specified Data Memory are first decremented by 1. If the result is 0 the

following instruction is skipped. As this requires the insertion of a dummy instruction while the next instruction is fetched, it is a two cycle instruction. If the result is not 0 the program

proceeds with the following instruction.

Operation $[m] \leftarrow [m] - 1$

Skip if [m]=0



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SDZA [m] Skip if decrement Data Memory is zero with result in ACC

Description The contents of the specified Data Memory are first decremented by 1. If the result is 0, the

following instruction is skipped. The result is stored in the Accumulator but the specified Data Memory contents remain unchanged. As this requires the insertion of a dummy

instruction while the next instruction is fetched, it is a two cycle instruction. If the result is not 0,

the program proceeds with the following instruction.

Operation $ACC \leftarrow [m] - 1$

Skip if ACC=0

Affected flag(s) None

SET [m] Set Data Memory

Description Each bit of the specified Data Memory is set to 1.

Operation $[m] \leftarrow FFH$ Affected flag(s) None

SET [m].i Set bit of Data Memory

Description Bit i of the specified Data Memory is set to 1.

 $\begin{array}{ll} \text{Operation} & \quad [m].i \leftarrow 1 \\ \text{Affected flag(s)} & \quad \text{None} \end{array}$

SIZ [m] Skip if increment Data Memory is 0

Description The contents of the specified Data Memory are first incremented by 1. If the result is 0, the

following instruction is skipped. As this requires the insertion of a dummy instruction while the next instruction is fetched, it is a two cycle instruction. If the result is not 0 the program

proceeds with the following instruction.

Operation $[m] \leftarrow [m] + 1$

Skip if [m]=0

Affected flag(s) None

SIZA [m] Skip if increment Data Memory is zero with result in ACC

Description The contents of the specified Data Memory are first incremented by 1. If the result is 0, the

following instruction is skipped. The result is stored in the Accumulator but the specified Data Memory contents remain unchanged. As this requires the insertion of a dummy

instruction while the next instruction is fetched, it is a two cycle instruction. If the result is not

0 the program proceeds with the following instruction.

Operation $ACC \leftarrow [m] + 1$

Skip if ACC=0

Affected flag(s) None

SNZ [m].i Skip if bit i of Data Memory is not 0

Description If bit i of the specified Data Memory is not 0, the following instruction is skipped. As this

requires the insertion of a dummy instruction while the next instruction is fetched, it is a two

cycle instruction. If the result is 0 the program proceeds with the following instruction.

Operation Skip if $[m].i \neq 0$

Affected flag(s) None

SUB A,[m] Subtract Data Memory from ACC

Description The specified Data Memory is subtracted from the contents of the Accumulator. The result is

stored in the Accumulator. Note that if the result of subtraction is negative, the C flag will be

cleared to 0, otherwise if the result is positive or zero, the C flag will be set to 1.

Operation $ACC \leftarrow ACC - [m]$

Affected flag(s) OV, Z, AC, C

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SUBM A,[m] Subtract Data Memory from ACC with result in Data Memory

Description The specified Data Memory is subtracted from the contents of the Accumulator. The result is

stored in the Data Memory. Note that if the result of subtraction is negative, the C flag will be

cleared to 0, otherwise if the result is positive or zero, the C flag will be set to 1.

Operation $[m] \leftarrow ACC - [m]$ Affected flag(s) OV, Z, AC, C

SUB A,x Subtract immediate data from ACC

Description The immediate data specified by the code is subtracted from the contents of the Accumulator.

The result is stored in the Accumulator. Note that if the result of subtraction is negative, the C flag will be cleared to 0, otherwise if the result is positive or zero, the C flag will be set to 1.

Operation $ACC \leftarrow ACC - x$ Affected flag(s) OV, Z, AC, C

SWAP [m] Swap nibbles of Data Memory

Description The low-order and high-order nibbles of the specified Data Memory are interchanged.

Operation [m].3 \sim [m].0 \leftrightarrow [m].7 \sim [m].4

Affected flag(s) None

SWAPA [m] Swap nibbles of Data Memory with result in ACC

Description The low-order and high-order nibbles of the specified Data Memory are interchanged. The

result is stored in the Accumulator. The contents of the Data Memory remain unchanged.

Operation $ACC.3 \sim ACC.0 \leftarrow [m].7 \sim [m].4$

 $ACC.7 \sim ACC.4 \leftarrow [m].3 \sim [m].0$

Affected flag(s) None

SZ [m] Skip if Data Memory is 0

Description If the contents of the specified Data Memory is 0, the following instruction is skipped. As this

requires the insertion of a dummy instruction while the next instruction is fetched, it is a two cycle instruction. If the result is not 0 the program proceeds with the following instruction.

Operation Skip if [m]=0

Affected flag(s) None

SZA [m] Skip if Data Memory is 0 with data movement to ACC

Description The contents of the specified Data Memory are copied to the Accumulator. If the value is zero,

the following instruction is skipped. As this requires the insertion of a dummy instruction while the next instruction is fetched, it is a two cycle instruction. If the result is not 0 the

program proceeds with the following instruction.

Operation $ACC \leftarrow [m]$

Skip if [m]=0

Affected flag(s) None

SZ [m].i Skip if bit i of Data Memory is 0

Description If bit i of the specified Data Memory is 0, the following instruction is skipped. As this requires

the insertion of a dummy instruction while the next instruction is fetched, it is a two cycle

instruction. If the result is not 0, the program proceeds with the following instruction.

Operation Skip if [m].i=0



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TABRD [m] Read table (specific page) to TBLH and Data Memory

Description The low byte of the program code (specific page) addressed by the table pointer pair

(TBHP and TBLP) is moved to the specified Data Memory and the high byte moved to TBLH.

Operation $[m] \leftarrow \text{program code (low byte)}$

 $TBLH \leftarrow program code (high byte)$

Affected flag(s) None

TABRDC [m] Read table (current page) to TBLH and Data Memory

Description The low byte of the program code (current page) addressed by the table pointer (TBLP) is

moved to the specified Data Memory and the high byte moved to TBLH.

Operation $[m] \leftarrow \text{program code (low byte)}$

TBLH ← program code (high byte)

Affected flag(s) None

TABRDL [m] Read table (last page) to TBLH and Data Memory

Description The low byte of the program code (last page) addressed by the table pointer (TBLP) is moved

to the specified Data Memory and the high byte moved to TBLH.

Operation $[m] \leftarrow \text{program code (low byte)}$

TBLH ← program code (high byte)

Affected flag(s) None

XOR A,[m] Logical XOR Data Memory to ACC

Description Data in the Accumulator and the specified Data Memory perform a bitwise logical XOR

operation. The result is stored in the Accumulator.

Operation $ACC \leftarrow ACC "XOR" [m]$

Affected flag(s) Z

XORM A,[m] Logical XOR ACC to Data Memory

Description Data in the specified Data Memory and the Accumulator perform a bitwise logical XOR

operation. The result is stored in the Data Memory.

Operation $[m] \leftarrow ACC "XOR" [m]$

Affected flag(s) Z

XOR A.x Logical XOR immediate data to ACC

Description Data in the Accumulator and the specified immediate data perform a bitwise logical XOR

operation. The result is stored in the Accumulator.

Operation $ACC \leftarrow ACC "XOR" x$

Affected flag(s) Z

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Package Information

Note that the package information provided here is for consultation purposes only. As this information may be updated at regular intervals users are reminded to consult the <u>Holtek website</u> for the latest version of the <u>Package/Carton Information</u>.

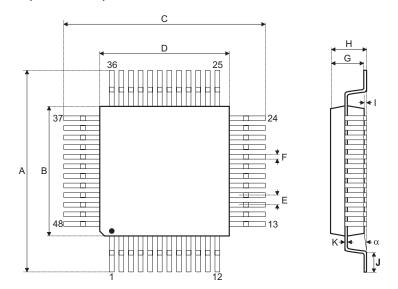
Additional supplementary information with regard to packaging is listed below. Click on the relevant section to be transferred to the relevant website page.

- Further Package Information (include Outline Dimensions, Product Tape and Reel Specifications)
- Packing Meterials Information
- · Carton information

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48-pin LQFP (7mm×7mm) Outline Dimensions



Symbol		Dimensions in inch		
Symbol	Min.	Nom.	Max.	
A	_	0.354 BSC	_	
В	_	0.276 BSC	_	
С	_	0.354 BSC	_	
D	_	0.276 BSC	_	
E	_	0.020 BSC	_	
F	0.007	0.009	0.011	
G	0.053	0.055	0.057	
Н	_	_	0.063	
I	0.002	_	0.006	
J	0.018	0.024	0.030	
K	0.004	_	0.008	
α	0°	_	7°	

Cymahal		Dimensions in mm	
Symbol	Min.	Nom.	Max.
A	_	9.00 BSC	_
В	_	7.00 BSC	_
С	_	9.00 BSC	_
D	_	7.00 BSC	_
E	_	0.50 BSC	_
F	0.17	0.22	0.27
G	1.35	1.40	1.45
Н	_	_	1.60
I	0.05	_	0.15
J	0.45	0.60	0.75
K	0.09	_	0.20
α	0°	_	7°

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BH67F2132 Ultra-Low Voltage R to F Flash MCU



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